

CMS32L051 Datasheet

ARM® Cortex®-M0+ based, ultra low power consumption 32-bit microcontroller

Built-in 64K byte Flash, rich analog function, timer and various communication interfaces

V1.9.4

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Features

- Ultra-low power operating environment:
 - Power supply voltage range: 1.8V to 5.5V
 - ➤ Temperature range: -40°C to 105°C
 - Low power consumption mode: sleep mode, deep sleep mode
 - Operating power consumption: 70uA/MHz@64MHz
 - Power consumption in deep sleep mode:80uA
- Core:
 - > ARM®32-bitCortex®-M0+ CPU
 - Working frequency: 32KHz~64MHz
- Memory:
 - 64KB Flash memory, with program and data storage shared
 - > 1.5KB dedicated data Flash memory
 - > 8KB SRAM memory with parity check

• Power and reset management:

- Built-in power-on reset (POR) circuit
- Built-in voltage detection (LVD) circuit (threshold voltage can be set)

• Clock management:

- Built-in high-speed vibrator, accuracy (±1%) .Can provide 2MHz~64MHz system clock and peripheral module operation clock
- Built-in 15KHz low-speed oscillator
- Support 1MHz~20MHz external crystal oscillator
- Support 32.768KHz external crystal oscillator, can be used to calibrate the internal high-speed vibrator
- Multiplier module:
 - Support single cycle 32bit multiplication operation
- Enhanced DMA controller:
 - Interrupt trigger start.
 - Transmission mode is selectable (normal transmission mode, repeated transmission mode, block transmission mode and chain transmission mode)
 - The transmission source/destination area is optional for the full address space range

• Analog peripheral:

12-bit precision ADC converter, conversion rate 500Ksps, 35 external analog channels, internal optional PGA0 output as conversion channel, with temperature sensor, support single-channel conversion mode and multichannel scan conversion mode Conversion range: 0 to positive reference voltage

Input/output port:

- Number of I/O port: 16~45
- Can switch between N-channel open drain and internal pull-up and pull-down
- > Built-in button interrupt detection function
- Built-in clock output/buzzer output control circuit

Serial two-wire debugger (SWD)

• Abundant timer:

- > 16-bit timer: 8 channels
- 15-bit interval timer: 1
- Real-time clock (RTC): 1 (with perpetual calendar, alarm clock function, and supports a wide range of clock correction)
- Watchdog timer (WWDT): 1
- SysTick timer

Abundant and flexible interface:

- 3-channel serial communication unit: each channel can be freely configured as a 1channel standard UART, 2-channel SPI or 2-channel simple I²C
- Standard SPI: 1 channel (support 8bit and16bit)
- Standard I²C: 1 channel
- IrDA: 1 channel

security function:

- Comply with relevant standards of IEC/UL 60730
- Abnormal storage space access error
- Support RAM parity check
- Support hardware CRC check
- Support important SFR protection to prevent misoperation
- > 128-bit unique ID number



• Linkage controller:

- The event signals can be linked together to realize the linkage of peripheral functions.
- 15 types of event input, 4 types of event trigger.
- Flash secondary protection in debug mode (Level1: only the entire Flash area can be erased, not read or write; Level2: the emulator connection is invalid, and Flash operation is not allowed)

Encapsulation:

 Support multiple encapsulation of 20Pin, 24Pin, 32Pin, 40Pin, 48 Pin

1 Overview

1.1 Introduction

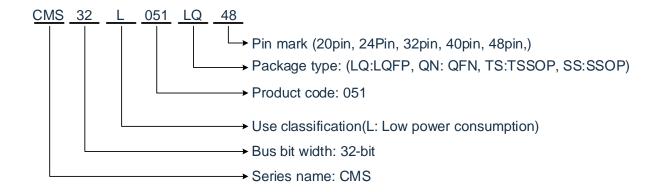
Ultra-low power consumption CMS32L051 uses high-performance 32-bit RISC core of ARM®Cortex®-M0+, can work at 64 MHz, and adopts high-speed embedded flash memory (SRAM max. 8KB, program/data flash memory max. 64KB) This product integrates multiple standard interfaces of I²C, SPI, UARTand LIN Integrated 12bit A/D converter, temperature sensor. Among them, the 12bit A/D converter can collect external sensor signals, reducing system design costs. The temperature sensor integrated in the chip can realize realtime monitoring of the external ambient temperature. Integrated 8-channel 16bit timer module, and equipped with EPWM control circuit, combined with the timer can realize the control of one DC motor or two stepper motors.

CMS32L051 also has excellent low-power performance, supports two low-power modes of sleep and deep sleep, and is designed to be flexible. Its operating power consumption is 70uA/MHz@64MHz, which is suitable for battery-powered low-power devices. At the same time, due to the integrated event linkage controller, direct connection between hardware modules can be realized without the intervention of the CPU, which is faster than using interrupt response, while reducing the frequency of CPU activity and prolonging the battery life.

These features make the CMS32L051 microcontroller series can be widely used in consumer civil products, such as household appliances, mobile devices, etc.



1.2 Product Model List



List of products of CMS32L051:

Number of Pin	Encapsulation	Product model
20pin	20-pin plastic package TSSOP (6.5X4.4mm, 0.65mm pitch)	CMS32L051TS20
20pin	20-pin plastic package QFN (3X3mm, 0.4mm pitch)	CMS32L051QN20
24pin	24pin 24-pin plastic package SSOP (8.65X3.9mm, 0.635mm pitch)	
24pin	24pin 24-pin plastic package QFN (4X4mm, 0.5mm pitch)	
32pin	32-pin plastic package QFN (5X5mm, 0.5mm pitch)	CMS32L051QN32
32pin	32-pin plastic package LQFP (7X7mm, 0.8mm pitch)	CMS32L051LQ32
40pin	40-pin plastic packageQFN (5X5mm, 0.4mm pitch)	CMS32L051QN40
48pin	48-pin plastic packageLQFP (7X7mm, 0.5mm pitch)	CMS32L051LQ48

FLASH, SRAM capacity:

Flash	Special data				CMS32L051		
memory	Flash memory	SRAM	20pin	24pin	32pin	40pin	48pin
0.41/2D	1.5KB	8KB	CMS32L051TS20	CMS32L051SS24			CMS32L051LQ48
64KB	1.9VD		CMS32L051QN20	CMS32L051QN24			CIVIS32L051LQ48



1.3 Pin Connection Diagram (Top View)

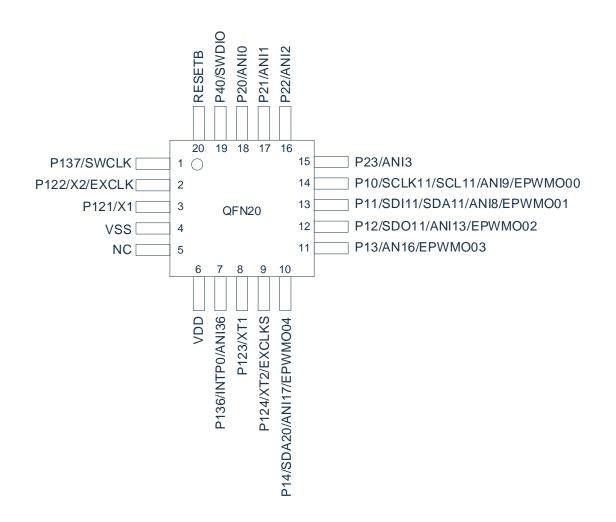
1.3.1 CMS32L051TS20 Pin Diagram





1.3.2 CMS32L051QN20 Pin Diagram

• 20-pin plastic package QFN (3x3mm, 0.4mm pitch)





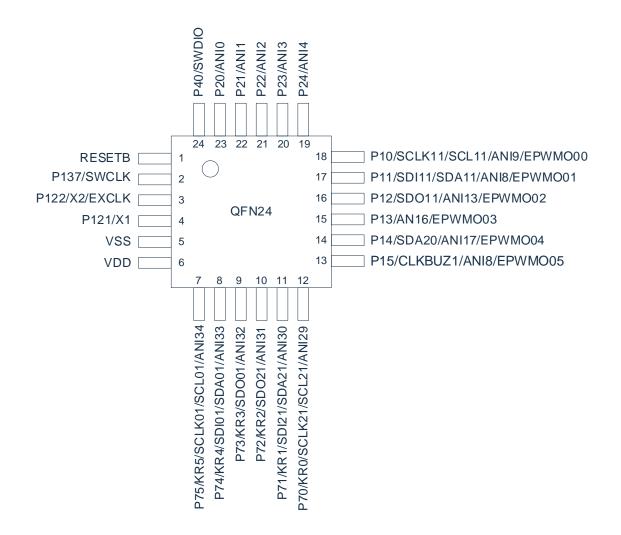
1.3.3 CMS32L051SS24 Pin Diagram





1.3.4 CMS32L051QN24 Pin Diagram

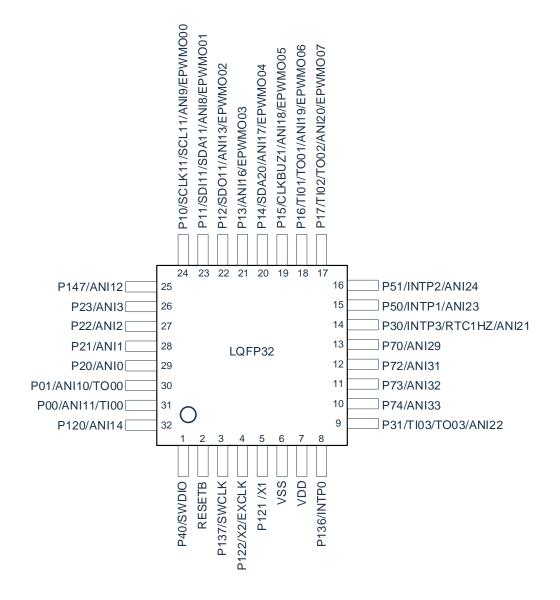
24-pin plastic package QFN (4x4mm, 0.5mm pitch)





1.3.5 CMS32L051LQ32 Pin Diagram

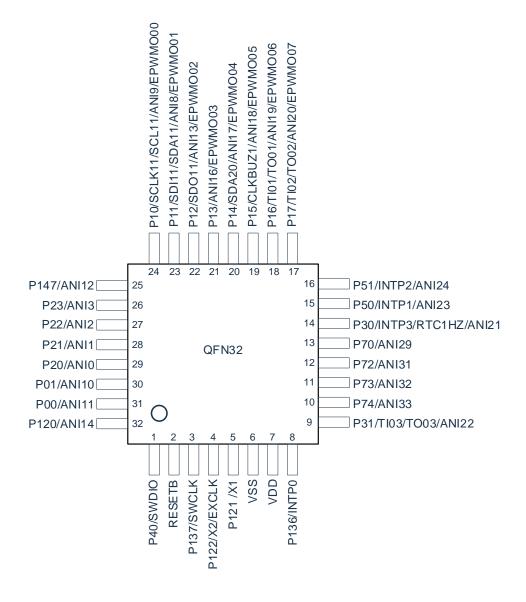
32-pin plastic package LQFP (7x7mm, 0.8mm pitch)





1.3.6 CMS32L051QN32 Pin Diagram

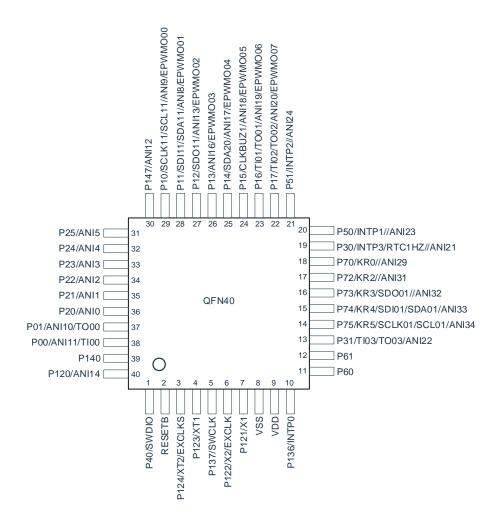
• 32-pin plastic package QFN (5x5mm, 0.5mm pitch)





1.3.7 CMS32L051QN40 Pin Diagram

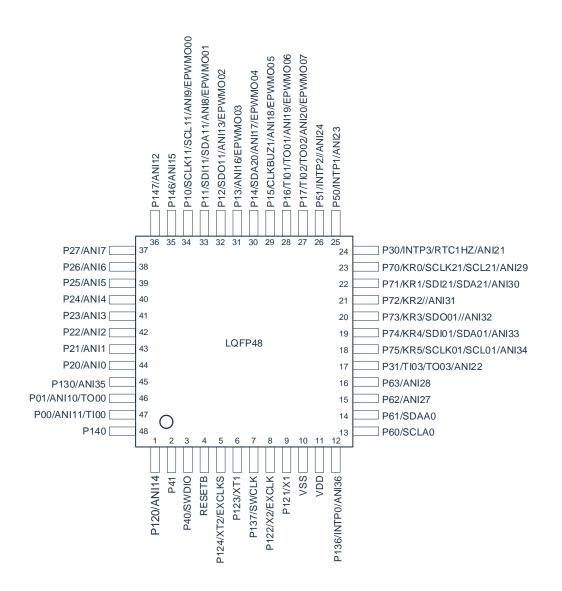
40-pin plastic package QFN (5x5mm, 0.4mm pitch)





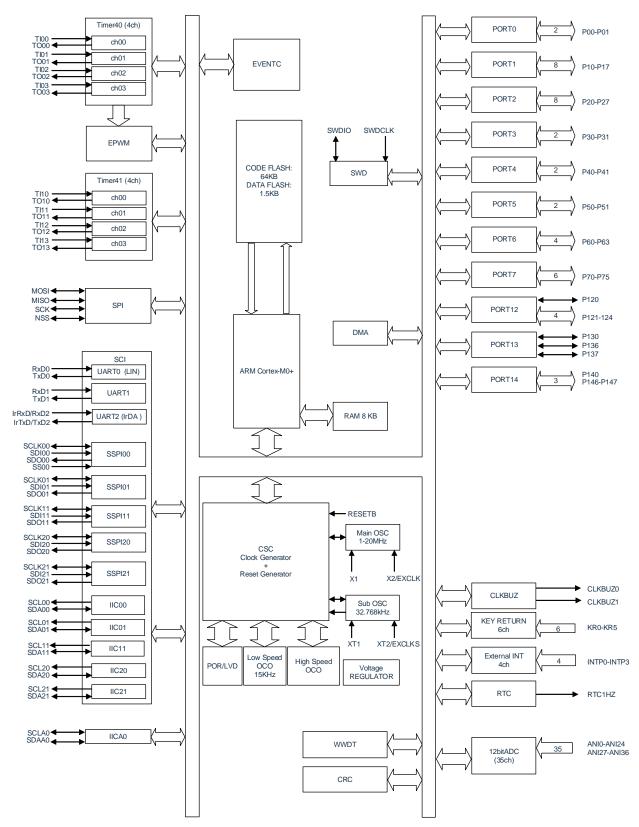
1.3.8 CMS32L051LQ48 Pin Diagram

48-pin plastic package LQFP (7x7mm, 0.5mm pitch)





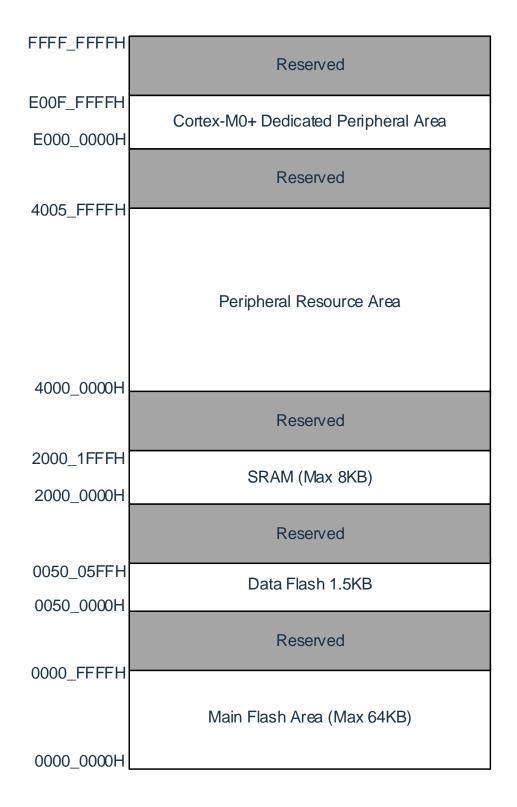
2 Product Structure Diagram



Remark: The above is for 48pin product. Some functions of products below 48pin are not supported.



3 Memory Mapping





4 Pin Function

4.1 **Port Function**

Table 4.1.1

Port	Port type	Reuse function	Digital output function set	Digital input function set		1	quippe	ed	1
name	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		register pxxcfg[3:0]	register xxxPCFG[5:0]	48 Pin	40 Pin	32 Pin	24 Pin	20 Pin
RESETB	Туре 3	RESETB	-	-					
		GPIO	00H	00H					
		ANI11	00H	00H					
P00		T100	00H	00H					
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		٠	٠		
		GPIO	00H	00H					
		ANI10	00H	00H					
P01		ТО00	00H	00H					
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	•		
		GPIO	00H	00H					
		ANI9	00H	00H					
		SCLK11	00H	00H					
P10		SCL11	00H	00H					
		epwmo00	00H	00H					
	Type 1	Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	•	٠	•
		GPIO	00H	00H					
		ANI8	00H	00H					
		SDI11	00H	00H					
P11		SDA11	00H	00H					
		epwmo01	00H	00H					
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		٠	٠	٠	٠
		GPIO	00H	00H					
		ANI13	00H	00H					
P12		SDO11	00H	00H					
		epwmo02	00H	00H					
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	•		•
P13		GPIO	00H	00H					
1 15		ANI16	00H	00H					



		epwmo03	00H	00H				
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	•	•	•	•
		GPIO	00H	00H				
		ANI17	00H	00H				
P14		SDA20	00H	00H				
		epwmo04	00H	00H				
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	٠	•	•	•
		GPIO	00H	00H		•	•	-
		ANI18	00H	00H			•	-
P15		CLKBUZ1	00H	00H				-
		epwmo05	00H	00H				-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	•	•	•	-
		GPIO	00H	00H			-	-
		ANI19	00H	00H			-	-
		TI01	00H	00H			-	-
P16		TO01	00H	00H			-	-
		(SPIMOSI)	00H	00H			-	-
		epwmo06	00H	00H			-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	•	•	-	-
	Type 1	GPIO	00H	00H			-	-
		ANI20	00H	00H			-	-
		TI02	00H	00H			-	-
P17		TO02	00H	00H			-	-
		(SPIMISO)	00H	00H			-	-
		epwmo07	00H	00H			-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	•	•	-	-
		GPIO	00H	00H				
P20		ANIO	00H	00H				
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	•	•	•	•
		GPIO	00H	00H				
P21		ANI1	00H	00H				
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	•	•	•	•
		GPIO	00H	00H				
P22		ANI2	00H	00H				
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	•	•
P23		GPIO	00H	00H				



		ANI3	00H	00H				
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•		•
		GPIO	00H	00H		-		-
P24		ANI4	00H	00H		-		-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		-	•	-
		GPIO	00H	00H		-	-	-
P25		ANI5	00H	00H		-	-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		-	-	-
		GPIO	00H	00H	-	-	-	-
P26		ANI6	00H	00H	-	-	-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	-	-	-	-
		GPIO	00H	00H	-	-	-	-
P27		ANI7	00H	00H	-	-	-	-
121		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	-	-	-	-
		GPIO	00H	00H			-	-
		ANI21	00H	00H			-	-
P30		INTP3	00H	00H			-	-
		RTC1HZ	00H	00H			-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	-	-
	Turne 4	GPIO	00H	00H		•	-	-
	Type 1	ANI22	00H	00H			-	-
P31		TI03	00H	00H			-	-
		TO03	00H	00H			-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)			-	-
		GPIO	00H	00H				
P40		SWDIO	00H	00H				
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	•	•	•	•
		GPIO	00H	00H	-	-	-	-
P41		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	-	-	-	-
		GPIO	00H	00H			-	-
		ANI23	00H	00H			-	-
P50		INTP1	00H	00H			-	-
		(SPINSS)	00H	00H		٠	-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	-	-
P51		GPIO	00H	00H			-	-



		ANI24	00H	00H				-	-
		INTP2	00H	00H				-	-
		(SPISCK)	00H	00H				-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	•	-	-
		GPIO	00H	00H			-	-	-
P60		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	-	-	-
		GPIO	00H	00H			-	-	-
P61		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)			-	-	-
		GPIO	00H	00H		-	-	-	-
P62		ANI27	00H	00H		-	-	-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	٠	-	-	-	-
		GPIO	00H	00H		-	-	-	-
P63		ANI28	00H	00H		-	-	-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		-	-	-	-
		GPIO	00H	00H		٠		٠	-
		ANI29	00H	00H		٠		٠	-
		KR0	00H	00H			-		-
P70		SCLK21	00H	00H		-	-		-
		SCL21	00H	00H		-	-		-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	•		-
		GPIO	00H	00H		-	-	٠	-
		ANI30	00H	00H		-	-		-
	Type 1	KR1	00H	00H		-	-		-
P71		SDI21	00H	00H		-	-		-
		SDA21	00H	00H		-	-		-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		-	-	•	-
		GPIO	00H	00H					-
		ANI31	00H	00H					-
P72		KR2	00H	00H			-		-
		SDO21	00H	00H		-	-		-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)					-
		GPIO	00H	00H					-
		ANI32	00H	00H					-
P73		KR3	00H	00H			-		-
		SDO01	00H	00H			-		-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	•	•	-



		GPIO	00H	00H					-
		ANI33	00H	00H					-
		KR4	00H	00H			-		-
P74		SDI01	00H	00H			-		-
		SDA01	00H	00H			-		-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	•	•	-
		GPIO	00H	00H			-		-
		ANI34	00H	00H			-		-
		KR5	00H	00H			-		-
P75		SCLK01	00H	00H	٠	•	-	•	-
		SCL01	00H	00H			-	•	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	•	•	-	•	-
		GPIO	00H	00H				-	-
P120	Type 1	ANI14	00H	00H				-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)				-	-
		GPIO	00H	00H					
P121		X1	00H	00H				٠	
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	•	•	•
		GPIO	00H	00H					
		X2	00H	00H					
P122		EXCLK	00H	00H					
	Type 2	Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	•	•	•
	1902	GPIO	00H	00H			-	-	
P123		XT1	00H	00H			-	-	
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)			-	-	
		GPIO	00H	00H			-	-	
Dict		XT2	00H	00H			-	-	
P124		EXCLKS	00H	00H			-	-	
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	-	-	•
		GPIO	00H	00H		-	-	-	-
P130		ANI35	00H	00H		-	-	-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		-	-	-	-
	Type 1	GPIO	00H	00H				-	
		ANI36	00H	00H				-	
P136		INTP0	00H	00H				-	
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•	•	-	•



		GPIO	00H	00H					
P137		SWCLK	00H	00H			٠		٠
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•			
		GPIO	00H	00H			-	-	-
P140		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)	•	•	-	-	-
		GPIO	00H	00H		-	-	-	-
P146		ANI15	00H	00H		-	-	-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		-	-	-	-
		GPIO	00H	00H				-	-
P147		ANI12	00H	00H				-	-
		Configurable digital functions	X (see table 4.1.2)	X (see table 4.1.2)		•		-	-
Vdd	-	Power supply	-	-					
Vss	-	Ground	-	-					

Remark: Refer to Section 4.3 for type 1, type 2 and type 3 port type structure diagrams.

Pin	Control register	Register configuration	Pin dual-purpose function
		4'h00	Default dual-use output
		4'h01	TO10
		4'h02	TO11
		4'h03	TO12
	P00cfg[3:0]~P147cfg[3:0]	4'h04	TO13
P00~P147		4'h05	SDO00/TxD0
		4'h06	SDO20/TxD2
		4'h07	CLKBUZ0
		4'h08	SCLKO00
		4'h09	SCLKO20
		4'h0a	TxD1

Table 4.1.2 Digital function configuration list (1/2 output function configuration)

Remark: P60 and P61 are NOD output, please pay attention when configuring and using.

Control register	Register configuration	Pin dual-purpose function
TI10PCFG	6'h00	Default dual-purpose input
TI11PCFG	6'h01	P00 as a dual input
TI12PCFG	6'h02	P01 as a dual input
TI13PCFG	6'h03	P10 as a dual input
INTPOPCFG	6'h04	P11 as a dual input
INTP1PCFG	6'h05	P12 as a dual input
INTP2PCFG	6'h06	P13 as a dual input
INTP3PCFG	6'h07	P14 as a dual input
SDI00PCFG (SPI/IIC/UART)	6'h08	P15 as a dual input
SCLKI00PCFG (SPI/IIC)	6'h09	P16 as a dual input
SS00PCFG (SPI)	6'h0a	P17 as a dual input
SDI20PCFG (SPI/UART)	6'h0b	P20 as a dual input
SCLKI20PCFG (SPI)	6'h0c	P21 as a dual input
RXD1PCFG (UART)	6'h0d	P22 as a dual input
SDAA0PCFG SCLA0PCFG	6'h0e	P23 as a dual input
SCLAUPEFG	6'h0f	P24 as a dual input
	6'h10	P25 as a dual input
	6'h11	P26 as a dual input
	6'h12	P27 as a dual input
	6'h13	P30 as a dual input
	6'h14	P31 as a dual input
	6'h15	P40 as a dual input
	6'h16	P41 as a dual input
	6'h17	P50 as a dual input
	6'h18	P51 as a dual input

Table 4.1.2 Digital function configuration list (2/2 input function configuration)



6'h19	P60 as a dual input
6'h1a	P61 as a dual input
6'h1b	P62 as a dual input
6'h1c	P63 as a dual input
6'h1d	P70 as a dual input
6'h1e	P71 as a dual input
6'h1f	P72 as a dual input
6'h20	P73 as a dual input
6'h21	P74 as a dual input
6'h22	P75 as a dual input
6'h23	P120 as a dual input
6'h24	P121 as a dual input
6'h25	P122 as a dual input
6'h26	P123 as a dual input
6'h27	P124 as a dual input
6'h28	P130 as a dual input
6'h29	P136 as a dual input
6'h2a	P137 as a dual input
6'h2b	P140 as a dual input
6'h2c	P146 as a dual input
 6'h2d	P147 as a dual input

Table 4.1.3 SPI pin function configuration list

Register name	Degister settings	SPI pin function mapping relationship					
	Register settings	SPINSS	SPISCK	SPIMISO	SPIMOSI		
	2'b00	Not mapped to any pins					
SPIPCFG [1:0]	2'b01	P50	P51	P17	P16		
SFIFGFG [1.0]	2'b10	P63	P31	P75	P74		
	2'b11	P25	P24	P23	P22		



4.2 Port Multiplexing Function

(1/2)

Function name	Input/output	Function	
ANIO ~ANI36	input	Analog input of A/D converter	
INTP0 ~INTP3	input	External interrupt request input Designation of valid edges: rising edge, falling edge, rising and falling double edges	
KR0 ~KR5	input	Key interrupt input	
CLKBUZ0, CLKBUZ1	output	Clock output / buzzer output	
RTC1HZ	output	Real-time clock correction clock (1Hz) output	
RESETB	input	Low-level active system reset input. When external reset is not used, it must be connected to V_{DD} directly or through a resistor.	
IrRxD	input	IrDA serial data input	
IrTxD	output	IrDA serial data output	
RxD0 ~RxD2	input	Serial data input of serial interface UART0, UART1, UART2	
TxD0 ~TxD2	output	Serial data output of serial interface UART0, UART1, UART2	
SCL00, SCL01, SCL11 SCL20, SCL21	output	Serial clock output of serial interface IIC00, IIC01, IIC11, IIC20, IIC21	
SDA00, SDA01, SDA11 SDA20, SDA21	input/ output	Serial data input/ output of serial interface IIC00, IIC01, IIC11, IIC20, IIC21	
SCLK00, SCLK01, SCLK11 SCLK20, SCLK21	input/ output	Serial clock input/ output of serial interface SSPI00, SSPI01, SSPI11, SSPI20, SSPI21	
SDI00, SDI01, SDI11, SDI20 SDI21	input	Serial data input of serial interface SSPI00, SSPI01, SSPI11, SSPI20, SSPI21	



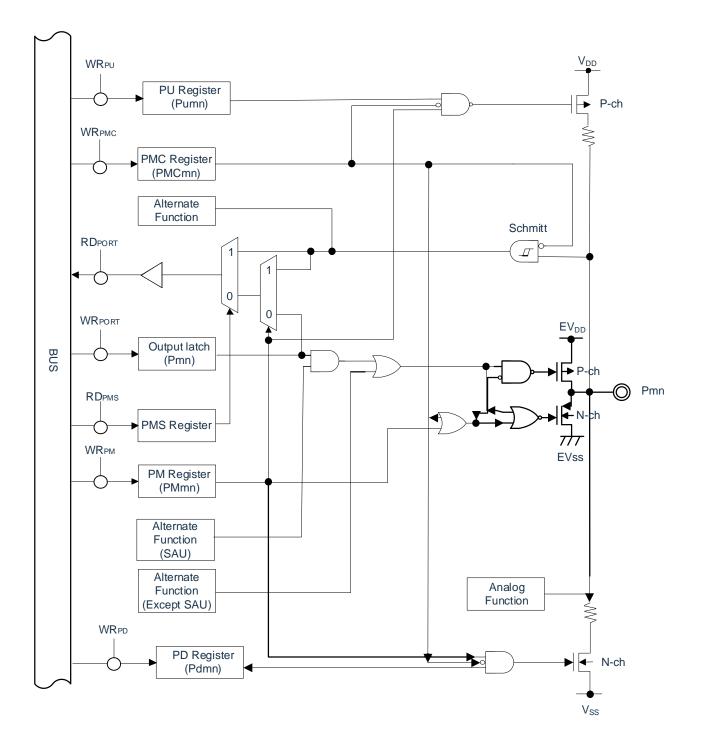
		(2/2)		
Function name	Input/output	Function		
SS00	input	Chip select input of serial interface SSPI00		
SDO00, SDO01, SDO11, SDO20, SDO21 output		Serial data output of SSPI00, SSPI01, SSPI11, SSPI20, SSPI21		
SPINSS	input	Chip select input of serial interface SPI		
SPISCK	Input/ output	Serial clock input/output of serial interface SPI		
SPIMISO	Input/ output	Serial data input/output of serial interface SPI		
SPIMOSI	Input/ output	Serial data input/output of serial interface SPI		
SCLA0	Input/ output	Clock input/output of serial interface IICA0		
SDAA0	Input/ output	Serial data input/output of serial interface IICA0		
TI00~TI03	input	16-bit timer Timer40 external count clock/capture trigger input		
TO00~TO03	output	Timer output of 16-bit timer Timer40		
TI10~TI13	input	16-bit timer Timer41 external count clock/capture trigger input		
TO10~TO13	output	Timer output of 16-bit timer Timer41		
X1, X2	—	Connect the resonator for the main system clock.		
EXCLK	input	External clock input of main system clock		
XT1, XT2	—	Connect the resonator for the subsystem clock.		
EXCLKS	input	External clock input for subsystem clock		
V _{DD}	_	Power supply		
V _{SS}	_	Groud		
SWDIO	input / output	SWD data interface		
SWCLK	input	SWD clock interface		

Remark: As a countermeasure for noise and locking, the bypass capacitor (about 0.1uF) must be connected with the shortest distance between V_{DD} and V_{SS} and thicker wiring.



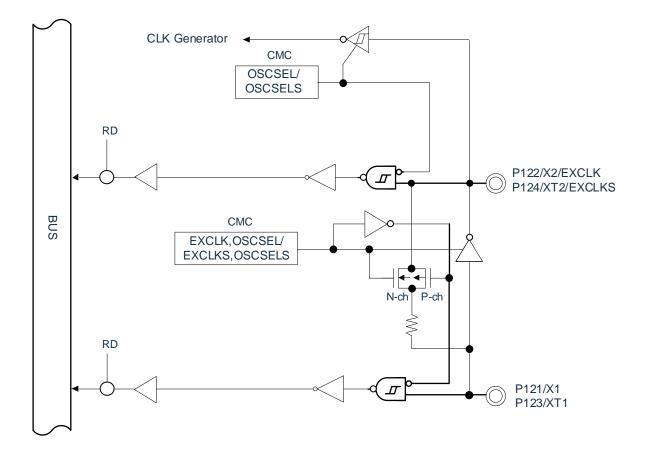
4.3 Port Type

Type 1: Dual I/O function

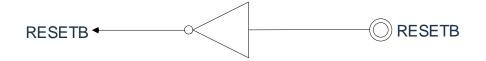




Type 2: CLK input function



Type 3: RESET function



5 Function Summary

5.1 ARM® Cortex®-M0+ Core

ARM's Cortex-M0+ processor is a new generation of ARM processors for embedded systems. It provides a low-cost platform designed to meet the needs of a small pin count and low-power microcontroller, while providing excellent computing performance and advanced system response to interrupts.

The 32-bit RISC processor of the Cortex-M0+ processor provides excellent code efficiency and the expected high performance of the ARM core, which is different from 8-bit and 16-bit devices of the same memory size. The Cortex-M0+ processor has 32 address lines and a storage space of up to 4G.

CMS32L051 uses an embedded ARM core, so it is compatible with all ARM tools and software.

5.2 Memory

5.2.1 Flash

CMS32L051 has a built-in flash memory that can be programmed, erased and rewritten. Has the following functions:

- > Programs and data share 64K storage space.
- > 1.5KB dedicated data Flash memory.
- Support page erasing, each page size is 512byte.
- Support byte/half-word/word (32bit) programming.

5.2.2 SRAM

CMS32L051 has built-in 8K bytes of embedded SRAM.



5.3 Enhanced DMA Controller

Built-in enhanced DMA (Direct Memory Access) controller can realize the function of data transfer between memories without using CPU.

- It supports the start of DMA through peripheral function interrupts, and can realize real-time control through communication, timer and A/D.
- The transmission source/destination area is optional for the entire address space range (when the Flash area is used as the destination address, the Flash needs to be preset to the programming mode).
- Supports 4 transfer modes (normal transfer mode, repetitive transfer mode, block transfer mode and chain transfer mode).

5.4 Linkage Controller

The linkage controller links each peripheral function output event with the peripheral function trigger source. So as to realize the coordinated operation between peripheral functions without using the CPU.

The linkage controller has the following functions:

- > The event signals can be linked together to realize the linkage of peripheral functions.
- > 15 types of event input, 4 types of event trigger.

5.5 Clock Generation and Start

The clock generation circuit is a circuit that generates a clock for the CPU and peripheral hardware. There are the following 3 types of system clocks and clock oscillation circuits.

5.5.1 Main System Clock

- X1 oscillator circuit: It can generate 1-20MHz clock oscillation by connecting a resonator to the pins (X1 and X2), and can stop the oscillation by executing a deep sleep command or setting MSTOP.
- High-speed internal oscillator (high-speed OCO): The frequency can be selected for oscillation by the option byte. After the reset is released, the CPU defaults to start running with this high-speed internal oscillator clock. Oscillation can be stopped by executing a deep sleep instruction or setting the HIOSTOP bit. The frequency set by the option byte can be changed through the frequency selection register of the high-speed internal oscillator. The highest frequency is 64Mhz, and the accuracy is ±1.0%.
- Input the external clock from the pin (X2): (1~20MHz), and the input of the external main system clock can be disabled by executing the deep sleep instruction or setting the MSTOP bit.

5.5.2 Subsystem Clock

- XT1 oscillator circuit: It can generate 32.768KHz clock oscillation by connecting a 32.768KHz resonator to the pins (XT1 and XT2), and the oscillation can be stopped by setting the XTSTOP bit.
- Input the external clock from the pin (XT2): 32.768KHz, and the input of the external clock can be disabled by setting the XTSTOP bit.

5.5.3 Low-speed Internal Oscillator Clock

Low-speed internal oscillator (low-speed OCO): generates 15KHz (Typ.) clock oscillation. The lowspeed internal oscillator clock can be used as the CPU clock. The following peripheral hardware can be run by the low-speed internal oscillator clock:

- Watchdog timer (WWDT)
- Real Time Clock (RTC)
- > 15-bit interval timer

5.6 **Power Management**

5.6.1 Power Supply Mode

VDD: external power supply, voltage range 1.8 to 5.5V

5.6.2 Power-on Reset

The power-on reset circuit (POR) has the following functions:

- An internal reset signal is generated when the power is turned on. If the power supply voltage (VDD) is greater than the detection voltage (VPOR), the reset is released. However, before reaching the operating voltage range, the reset state must be maintained through a voltage detection circuit or an external reset.
- The power supply voltage (VDD) and the detection voltage (VPDR) are compared. When VDD <VPDR, an internal reset signal is generated. However, when the power supply drops, it must be shifted to the deep sleep mode before it falls below the operating voltage range, or set to the reset state through a voltage detection circuit or an external reset. If you want to restart operation, you must confirm that the power supply voltage has returned to the operating voltage range.</p>

5.6.3 Voltage Detection

The voltage detection circuit sets the operation mode and detection voltage (V_{LVDH} , V_{LVDL} , V_{LVD}) through the option byte. The voltage detection (LVD) circuit has the following functions:

- Compare the power supply voltage (V_{DD}) with the detection voltage (V_{LVDH}, V_{LVDL}, V_{LVD}) and generate an internal reset or interrupt request signal.
- The detection voltage of the power supply voltage (V_{LVDH}, V_{LVDL}, V_{LVD}) can select the detection level by the option byte.
- Can run in deep sleep mode.
- When the power supply rises, before reaching the operating voltage range, the reset state must be maintained through a voltage detection circuit or an external reset. When the power supply drops, it must be transferred to the deep sleep mode before being lower than the operating voltage range, or set to the reset state through a voltage detection circuit or an external reset.
- > The operating voltage range varies according to the setting of the user option byte.

5.7 Low Power Consumption Mode

CMS32L051 supports two low-power modes to achieve the best compromise between low power consumption, short startup time, and available wake-up sources.

- Sleep mode: Enter the sleep mode by executing the sleep command. The sleep mode is a mode in which the CPU operating clock is stopped. Before setting the sleep mode, if the high-speed system clock oscillator circuit, high-speed internal oscillator, or subsystem clock oscillator circuit is oscillating, each clock continues to oscillate. Although this mode cannot reduce the operating current to the level of the deep sleep mode, it is an effective mode when you want to restart processing immediately through an interrupt request or when you want to perform intermittent operation frequently.
- Deep sleep mode: Enter the deep sleep mode by executing the deep sleep command. The deep sleep mode is a mode to stop the oscillation of the high-speed system clock oscillation circuit and the high-speed internal oscillator and stop the entire system. Can greatly reduce the operating current of the chip. Because the deep sleep mode can be cancelled by an interrupt request, intermittent operation is also possible. However, in the case of the X1 clock, because it is necessary to ensure the wait time for stable oscillation when releasing the deep sleep mode, if you must start processing immediately with an interrupt request, you must select the sleep mode.

In the two low-power modes mentioned above, the registers, flags, and data memory remain in the state before standby mode, and the output latch and output buffer of the input/output ports will also remain in the state before standby.

5.8 Reset Function

The following 7 methods to generate a reset signal:

- 1) Input external reset through RESETB pin.
- 2) Generate an internal reset through the program runaway detection of the watchdog timer.
- 3) The internal reset is generated by comparing the power supply voltage of the power-on reset (POR) circuit and the detection voltage.
- 4) The internal reset is generated by comparing the power supply voltage of the voltage detection circuit (LVD) and the detection voltage.
- 5) Internal reset due to RAM parity error.
- 6) Internal reset due to access to illegal memory.
- 7) Software reset

The internal reset is the same as the external reset. After the reset signal is generated, the program is executed from the addresses written in addresses 0000H and 0001H.

5.9 Interrupt Function

The Cortex-M0+ processor has a built-in nested vectored interrupt controller (NVIC), which supports up to 32 interrupt request (IRQ) inputs and 1 non-maskable interrupt (NMI) input. In addition, the processor also supports multiple internal exceptions.

This product has processed 32 maskable interrupt requests (IRQ) and 1 non-maskable interrupt (NMI). For details, please refer to the corresponding chapters of the user manual. The actual number of interrupt sources varies by product.

5.10 Real Time Clock (RTC)

The real-time clock (RTC) has the following functions.

- Counter with year, month, week, day, hour, minute and second.
- > Fixed period interrupt function (period: 0.5 second, 1 second, 1 minute, 1 hour, 1 day, 1 month)
- > Alarm interrupt function (alarm clock: week, hour, minute)
- > 1Hz pin output function
- Support the division of the subsystem clock or the main system clock as the running clock of the RTC
- > The real-time clock interrupt signal (INTRTC) can be used as a wake-up from deep sleep mode
- > Support a wide range of clock correction functions

Only when the sub-system clock (32.768KHz) or the divided frequency of the main system clock is selected as the running clock of the RTC, the year, month, week, day, hour, minute and second can be counted. When the low-speed internal oscillator clock (15KHz) is selected, only the fixed cycle interrupt function can be used.

5.11 Watchdog Timer

1 channel WWDT, 17bit watchdog timer is set to count operation by option byte. The watchdog timer runs on the low-speed internal oscillator clock (15KHz). The watchdog timer is used to detect program runaway. When a program out of control is detected, an internal reset signal is generated.

The following conditions are judged to be out of control of the program:

- When the watchdog timer counter overflows
- > When a 1-bit operation instruction is executed on the enable register (WDTE) of the watchdog timer
- > When writing data other than "ACH" to the WDTE register
- > When writing data to the WDTE register while the window is closed

5.12 SysTick Timer

This timer is dedicated to the real-time operating system, but it can also be used as a standard down counter.

Its characteristics are: when the 24-bit down counter self-filling capacity counter reaches 0, a maskable system interrupt is generated.

5.13 Timer Timer4

This product has two built-in timer units Timer4 with 4-channel 16-bit timers each 16-bit timer is called a "channel", which can be used as an independent timer or combined with multiple channels for advanced timer functions.

For details of each function, please refer to the table below:

	Independent channel operation function		Multi-channel linkage operation function
•	Interval timer	•	One-shot pulse output
•	Square wave output	•	PWM output
•	External event counter	•	Multiple PWM output
•	Frequency divider		
Measurement of input pulse interval			
• Measurement of the high/low level width of the input			
	signal		
•	Delay counter		

5.13.1 Independent Channel Operation Function

The independent channel operation function is a function that can independently use any channel without being affected by the operation mode of other channels. The independent channel operation function can be used in the following modes:

- 1) Interval timer: Can be used as a reference timer that generates interrupts (INTTM) at regular intervals.
- 2) Square wave output: Whenever an INTTM interrupt is generated, a flip is triggered, and a square wave with a 50% duty cycle is output from the timer output pin (TO).
- 3) External event counter: Count the valid edge of the input signal of the timer input pin (TI), and if it reaches the specified number of times, it can be used as an event counter to generate an interrupt.
- 4) Frequency divider function (only limited to channel 0 of unit 0): divide the input clock of the timer input pin (TI00), and then output from the output pin (TO00).
- 5) Input pulse interval measurement: start counting at the valid edge of the input pulse signal of the timer input pin (TI) and capture the count value at the valid edge of the next pulse to measure the interval of the input pulse.
- 6) Measurement of the high/low level width of the input signal: start counting on one edge of the input signal of the timer input pin (TI) and capture the count value on the other edge to measure the high or low level of the input signal Width.
- 7) Delay counter: start counting at the valid edge of the input signal of the timer input pin (TI) and generate an interrupt after any delay period has elapsed.

5.13.2 Multi-channel Linkage Operation Function

Multi-channel linkage operation function can be realized by combining the master channel (the basic timer of the main control cycle) and the slave channel (the timer that follows the master control channel). Multi-channel linkage operation function can be used in the following modes:

- 1) One-shot pulse output: Use two channels in pairs to generate one-shot pulses that can set the output timing and pulse width arbitrarily.
- 2) PWM (Pulse Width Modulation) output: Use 2 channels in pairs to generate pulses with a period and duty cycle that can be set arbitrarily.
- 3) Multiple PWM (Pulse Width Modulation) output: It can generate up to 7 kinds of PWM signals with any duty cycle in a fixed cycle by expanding the PWM function and using 1 master channel and multiple slave channels.

5.13.3 8-bit Timer Operation Function

The 8-bit timer operation function can use the 16-bit timer channel as a function of two 8-bit timer channels. (Only channel 1 and channel 3 can be used)

5.13.4 LIN-bus Support Function

The Timer4 unit can be used to check whether the received signal in LIN-bus communication is suitable for the LIN-bus communication format.

- Wake-up signal detection: Start counting on the falling edge of the input signal of the UART serial data input pin (RxD) and capture the count value on the rising edge to measure the low-level width. If the low-level width is greater than or equal to a certain fixed value, it is considered as a wake-up signal.
- 2) Interval field detection: After detecting the wake-up signal, start counting from the falling edge of the input signal of the UART serial data input pin (RxD) and capture the count value on the rising edge to measure the low-level width. If the width of the low level is greater than or equal to a certain fixed value, it is regarded as an interval field.
- Synchronous field pulse width measurement: After detecting the interval field, measure the lowlevel width and high-level width of the input signal of the UART serial data input pin (RxD).
 Calculate the baud rate based on the bit interval of the sync field measured in this way.

5.14 EPWM Output Control Circuit

Use Timer4's PWM output function to control one DC motor or two stepping motors.

5.15 15-bit Interval Timer

This product has a built-in 15-bit interval timer, which can generate interrupts (INTIT) at any time interval set in advance, and can be used to wake up from deep sleep mode.

5.16 Clock Output/Buzzer Output Control Circuit

The clock output controller is used to provide the clock to the peripheral IC, and the buzzer output controller is used to output the square wave of the buzzer frequency. Clock output or buzzer output is realized by dedicated pins.

5.17 Universal Serial Communication Unit

This product has two built-in universal serial communication units, and each unit has up to 4 serial communication channels. It can realize the communication functions of standard SPI, simple SPI, UART and simple I²C. Take the 48pin product as an example, the function allocation of each channel is as follows.

5.17.1 3-wire Serial Interface (Simple SPI)

Synchronize data transmission and reception with the serial clock (SCK) output from the master control device.

This is a clock synchronous communication interface that uses 1 serial clock (SCK), 1 sending serial data (SO), and 1 receiving serial data (SI) to communicate with a total of 3 communication lines.

[Data transmission and reception]

- > 7-bit or 8-bit data length
- Phase control of sending and receiving data
- MSB/LSB priority choice

[Clock control]

- > Choice of master control or slave
- Phase control of input/output clock
- > The transmission cycle generated by the prescaler and the internal counter of the channel
- Maximum transfer rate
 - Master communication: Max FCLK/2
 - Slave communication: Max F_{MCK}/6

[Interrupt function]

> Transmission end interrupt, buffer empty interrupt

[Error detection flag]

Overflow error



5.17.2 Simple SPI with Slave Chip Select Function

SPI serial communication interface supporting slave chip select input function. This is a clock synchronization that uses a slave chip select input (SSI), a serial clock (SCK), a sending serial data (SO), and a receiving serial data (SI) 4 communication lines for communication. Communication Interface.

[Data sending and receiving]

- 7-bit or 8-bit data length
- > Phase control of sending and receiving data
- MSB/LSB priority choice
- > Level setting of sending and receiving data

[Clock control]

- Phase control of input/output clock
- > The transmission cycle generated by the prescaler and the internal counter of the channel
- > Maximum transfer rate
 - Slave communication: Max F_{MCK}/6

[Interrupt function]

> Transmission end interrupt, buffer empty interrupt

[Error detection flag]

> Overflow error



5.17.3 UART

The function of asynchronous communication through two lines of serial data transmission (TxD) and serial data reception (RxD). Use these two communication lines to send and receive data asynchronously (using the internal baud rate) with other communication parties according to the data frame (consisting of start bit, data, parity bit and stop bit). Full-duplex UART communication can be realized by using two channels dedicated for transmission (even-numbered channels) and dedicated for reception (odd-numbered channels), and LIN-bus can be supported by combining Timer4 units and external interrupts (INTPO).

[Data sending and receiving]

- > 7-bit, 8-bit or 9-bit data length
- MSB/LSB priority choice
- > Selection of level setting and reverse phase of sending and receiving data
- > Additional parity check bit, parity check function
- Additional stop bit, stop bit detection

[Interrupt function]

- > Transmission end interrupt, buffer empty interrupt
- > Error interrupt caused by framing error, parity error or overflow error

[Error detection flag]

> Frame error, parity error, overflow error

[LIN-bus function]

- Wake-up signal detection
- BF detection
- > Measurement of synchronization field, calculation of baud rate

5.17.4 Simple I²C

The function of clock synchronization communication with multiple devices through two lines of serial clock (SCL) and serial data (SDA). Because this simple I²C is designed for single communication with flash memory, A/D converters and other devices, it can only be used as a master device. The start condition and stop condition are the same as the operation control register, and must comply with the AC characteristics and be processed by software.

[Data sending and receiving]

- Main control sending, main control receiving (only limited to the main control function of single main control)
- > ACK output function, ACK detection function
- 8-bit data length (when sending the address, use the upper 7 bits to specify the address, and use the lowest bit for R/W control)
- > Generate start and stop conditions through software

[Interrupt function]

> End of transmission interrupt

[Error detection flag]

ACK error, overflow error

[Functions not supported by simple I²C]

- Slave sending, slave receiving
- > Multi-master control function (arbitration failure detection function)
- Waiting for detection function

5.18 Standard Serial Peripheral Interface (SPI)

The serial interface SPI has the following 2 modes:

- Operation stop mode: This is a mode used when serial transmission is not performed, which can reduce power consumption
- 3-wire serial I/O mode: This mode uses 3 lines of serial clock (SCK) and serial data bus (MISO and MOSI) to transmit 8-bit or 16-bit data with multiple devices.

5.19 Standard Serial Interface (IICA)

The serial interface IICA has the following 3 modes:

- Operation stop mode: This is a mode used when serial transmission is not performed, which can reduce power consumption.
- I²C bus mode (supports multiple masters): This mode uses 2 lines of serial clock (SCLA) and serial data bus (SDAA) to transmit 8-bit data with multiple devices. In line with the I²C bus format, the master device can generate "start condition", "address", "indication of the transfer direction", "data" and "stop condition" for the slave device on the serial data bus. The slave device automatically detects the received status and data through hardware. This function can simplify the I²C bus control part of the application. Because the SCLA pin and SDAA pin of the serial interface IICA are used as open-drain output, the serial clock line and the serial data bus require a pull-up resistor.
- Wake-up mode: In the deep sleep mode, when the extension code or the local station address from the autonomous control device is received, the deep sleep mode can be released by generating an interrupt request signal (INTIICA). Set through the IICA control register

5.20 Analog-to-digital Converter (ADC)

This product has a built-in 12-bit resolution analog-to-digital converter SARADC, which can convert analog input to digital value and supports up to 35 channels of ADC analog input (ANI0~ANI24, ANI27~ANI36). The ADC contains the following functions:

- > 12-bit resolution, conversion rate 500Ksps.
- > Trigger mode: support software trigger, hardware trigger and hardware trigger in standby state
- > Channel selection: support two modes of single-channel selection and multi-channel scanning
- > Conversion mode: support single conversion and continuous conversion
- ➢ Working voltage: Support the working voltage range of 1.8V≤VDD≤5.5V
- > It can detect the built-in reference voltage (1.45V) and temperature sensor.

	Software trigger	Start the conversion by software operation.			
Trigger mode	Hardware trigger no wait mode	Start the conversion by detecting the hardware trigger.			
Trigger mode		In the conversion standby state with the power off, the power is turned on			
	Hardware trigger wait mode	by detecting the hardware trigger, and the conversion starts			
		automatically after the A/D power stabilization wait time.			
	Select mode	Select 1 channel of analog input for A/D conversion.			
Channel		Perform A/D conversion on 4 channels of analog input in sequence. It is			
selection mode	Scan mode	possible to select 4 consecutive channels from ANI0 to ANI15 as analog			
		input.			
Conversion	Single conversion mode	Perform 1 A/D conversion on the selected channel.			
Conversion	Continuous conversion mode	Perform continuous A/D conversion on the selected channel until it is			
mode	Continuous conversion mode	stopped by software.			
Sampling	Number of sampling	The sampling time can be set by the register. The default value of the			
time/conversion	clocks/number of conversion	sampling clock is 4 clk, and the Min value of the conversion clock is 16			
time	clocks	clk.			

ADC can set various A/D conversion modes through the following mode combinations.

5.21 Two-wire Serial Debug Port (SW-DP)

ARM's SW-DP interface allows to connect to the microcontroller through a serial wire debugging tool.

5.22 Security Function

5.22.1 Flash CRC Calculation Function (High-speed CRC, general-purpose CRC)

According to different purposes and conditions of use, the following 2 CRCs can be used respectively.

- High-speed CRC: In the initialization program, it can stop the operation of the CPU and check the entire code flash area at high speed.
- General CRC: In CPU operation, it is not limited to the code flash area but can be used for multipurpose checking.

5.22.2 RAM Parity Error Detection Function

When reading RAM data, detect parity errors.

5.22.3 SFR Protection Function

Prevent the important SFR (Special Function Register) from being rewritten due to CPU runaway.

5.22.4 Illegal Memory Access Detection Function

Detect illegal access to illegal memory area (area without memory or area with restricted access).

5.22.5 Frequency Detection Function

Can use Timer4 unit to self-check CPU or peripheral hardware clock frequency.

5.22.6 A/D Test Function

The A/D converter is self-tested by performing A/D conversion on the A/D analog input channel (ANI), temperature sensor output voltage, and internal reference voltage.

5.22.7 Digital Output Signal Level Detection Function of Input/ Output Port

When the input/output port is in output mode, the output level of the pin can be read.



5.23 Key Function

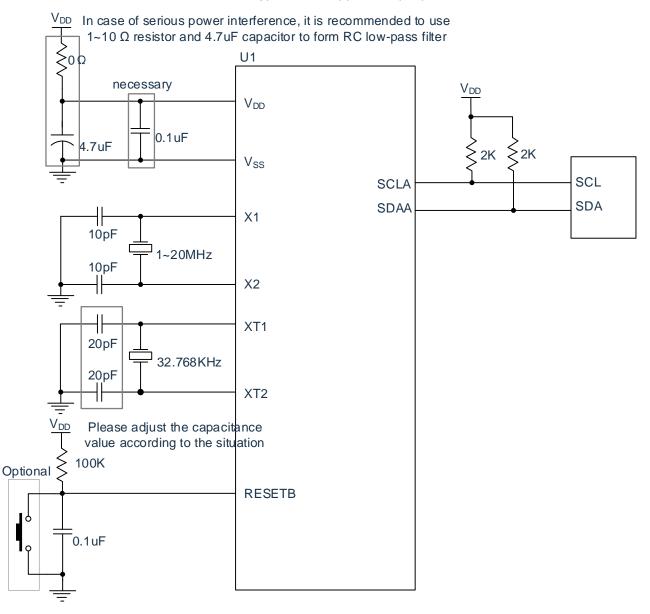
The input pin (KR0~KR4) can be interrupted by the key to generate a key interrupt (INTKR).



6 Electrical Characteristics

6.1 **Typical Application Peripheral Circuit**

The device connection reference of the typical MCU application peripheral circuit is as follows:



6.2 Absolute Maximum Voltage Rating

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(T _A = -	40~10	ກເມ

Item	Symbol	Condition	Rating	Unit
Source voltage	V _{DD}	-	-0.5~+6.5	V
		P00~P01, P10~P17, P20~P27, P30~P31		
	VI1	P40~P41, P50~P51, P62~P63, P70~P75	-0.3~V _{DD} +0.3 Note1	V
Input voltage	V I1	P120~P124, P130, P136, P137, P140, P146	-0.3~VDD+0.3	v
		P147, EXCLK, EXCLKS, RESETB		
	V _{I2}	P60~P61 (N-channel open drain)	-0.3~+6.5	V
	Vo	P00~P01, P10~P17, P20~P27, P30~P31		
Output voltage		P40~P41, P50~P51, P60~P63, P70~P75, P120	-0.3~V _{DD} +0.3 Note1	V
		P130, P136, P137, P140, P146, P147		
Analog input	Vai	ANI0~ANI24, ANI27~ANI36	-0.3~V _{DD} +0.3 Note1	V
voltage	V AI	AINIO ~ AINI24, AINI27 ~ AINI30	-0.3~vDD+0.3	V

Note1: Do not exceed 6.5V.

Caution: Even if one of the items exceeds the absolute maximum rating for an instant, the quality of the product may be degraded. The absolute maximum rating is a rating that may cause physical damage to the product, and the product must be used under the condition that the rating is not exceeded.

Remarks:

- 1. Unless otherwise specified, the characteristics of multiplexed pins are the same as those of port pins.
- 2. Use V_{SS} as the reference voltage.

6.3 Absolute Maximum Current Rating

Item	Symbol		Condition	Rating	Unit
		Each pin	P00~P01, P10~P17, P20~P27, P30~P31 P40~P41, P50~P51, P60~P63, P70~P75, P120 P130, P136, P137, P140, P146, P147	-15	mA
High level output current	Іон1	Total pins	P00~P01, P20~P27, P40~P41, P120, P130 P136, P137, P140	-70	mA
		-170mA	P10~P17, P30~P31, P50~P51, P60~P63 P70~P75, P146, P147	-100	mA
	I _{OH2}	Each pin	P121~P124	-3	mA
	IOH2	Total pins		-15	mA
		Each pin	P00~P01, P10~P17, P20~P27, P30~P31 P40~P41, P50~P51, P60~P63, P70~P75, P120 P130, P136, P137, P140, P146, P147	40	mA
Low-level output	I _{OL1}	Total pins	P00~P01, P20~P27, P40~P41, P120, P130 P136, P137, P140	100	mA
Gunem		170mA	P10~P17, P30~P31, P50~P51, P60~P63 P70~P75, P146, P147	120	mA
	la	Each pin	P121~P124	15	mA
	Iol2	Total pins	□ □ □ 2 1 ~ □ 1 2 4	45	mA
Working temperature	TA	Normally run When flash pre	lormally run Vhen flash programming		Û
Storage temperature	T _{stg}		-	-65~150	°C

Caution: Even if one of the items exceeds the absolute maximum rating for an instant, the quality of the product may be degraded. The absolute maximum rating is a rating that may cause physical damage to the product, and the product must be used under the condition that the rating is not exceeded.

6.4 Oscillation Circuit Characteristics

6.4.1 X1, XT1 Characteristics

(T _A = -40~105°C, 1.8V≤V _{DD} ≤5.5V, V _{SS} =	0V)
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Item	Resonator	Condition	Min	Тур	Max	Unit
X1 clock oscillation	Ceramic resonator/	1.8V≤V _{DD} ≤5.5V	1.0	-	20.0	MHz
frequency (Fx)	crystal resonator					
XT1 clock oscillation	Crystal resonator	1.8V≤Vpp≤5.5V	32	32,768	35	KHz
frequency (F _{XT})	Crystal resolitator	1.6V≪VDD≪5.5V	32	32.700	35	κΠΖ

Remark:

- 1. It only indicates the allowable frequency range of the oscillation circuit. Please refer to the AC characteristics for the command execution time.
- 2. Please entrust the resonator manufacturer to evaluate after installing the circuit, and use it after confirming the oscillation characteristics.

6.4.2 Internal Oscillator Characteristics

(T_A= -40~105°C, 1.8V≤V_{DD}≤5.5V, V_{SS}=0V)

Resonator	Condition	Min	Тур	Max	Unit
High-speed internal oscillator clock frequency (FIH) Note1,2	-	2.0	-	64.0	MHz
Clock frequency accuracy of high-	T _A =0~70°C	-1.0	-	+1.0	%
speed internal oscillator	T _A = -40~105°C	-1.5 Note3	-	+1.5 Note3	%
Clock frequency of low-speed internal oscillator (FIL)	-	10	15	20	KHz

Note1: Select the frequency of the high-speed internal oscillator by the option byte.

Note2: It only shows the characteristics of the oscillation circuit, please refer to the AC characteristics for the command execution time.

Note3: Low temperature specification value is guaranteed by design, mass production does not measure low temperature condition.



6.5 DC Characteristics

6.5.1 Pin Characteristics

Item	Symbol	Condition		Min	Тур	Max	Unit
		P00~P01, P10~P17, P20~P27	$1.8V \leq V_{DD} \leq 5.5V$			-12.0 Note2	
		P30~P31, P40~P41, P50~P51	-40~85°C	-	-	-12.0	
		P60~P63, P70~P75, P120, P130	1.8V≤V _{DD} ≤5.5V				mA
		P136, P137, P140, P146, P147	85~105°C	-	-	-6.0 Note2	
		1 pin alone					
			4.0V≤V _{DD} ≤5.5V	-	-	-60.0	
		P00~P01, P20~P27, P40~P41 P120, P130, P136, P137, P140 Total pins	-40~85°C			-30.0	mA
			4.0V≤V _{DD} ≤5.5V	-	-		
	Іон1		85~105°C				
		(when duty cycle \leq 70% ^{Note3})	2.4V≤V _{DD} <4.0V	-	-	-12.0	mA
high level			1.8V≤V _{DD} <2.4V	-	-	-6.0	mA
output		P10~P17, P30~P31, P50~P51 P60~P63, P70~P75, P146, P147	4.0V≤V _{DD} ≤5.5V	-	-	-80.0	mA
Current			-40~85°C				
Note1			4.0V≤V _{DD} ≤5.5V	-	-	-30.0	
		Total pins	85~105°C			00.0	
		(when duty cycle \leq 70% ^{Note3})	2.4V≤V _{DD} <4.0V	-	-	-20.0	mA
			1.8V≤V _{DD} <2.4V	-	-	-10.0	mA
			1.8V≤V _{DD} ≤5.5V	_	_	-140.0	mA
		Total pins	-40~85°C	-	_	-140.0	
		(when duty cycle \leq 70% Note3)	1.8V≤V _{DD} ≤5.5V			60.0	III/A
			85~105°C	-	-	-60.0	
		P121 ~ P124 1 pin alone	1.8V≤V _{DD} ≤5.5V	-	-	-2.5 Note2	mA
	Іон2	Total pins (when duty cycle ≤70% ^{Note3})	1.8V≤V _{DD} ≤5.5V	-	-	-10	mA

Note1: This is the current value that guarantees the operation of the device even if current flows from the V_{DD} pin to the output pin.

Note2: Can not exceed the total current value.

Note3: This is the output current value of "duty cycle≤70%condition".

To change the output current value with a duty cycle >70% can be calculated with the following calculation formula (when the duty cycle is changed to n%).

The total output current of the pins = $(I_{OH} \times 0.7)/(n \times 0.01)$

<example> I_{OH} = -10.0mA, n =80%

The total output current of the pins = $(-10.0 \times 0.7)/(80 \times 0.01) \approx -8.7$ mA

The current of each pin does not change due to the duty cycle, and no current above the absolute maximum rating will flow.



Item	Symbol	Condition		Min	Тур	Max	Unit
		P00~P01, P10~P17, P20~P27 P30~P31, P40~P41, P50~P51	1.8V≤V _{DD} ≤5.5V -40~85°C	-	-	35 ^{Note2}	
		P60~P63, P70~P75, P120, P130 P136, P137, P140, P146, P147 1 pin alone	1.8V≪V _{DD} ≪5.5V 85~105°C	-	-	20 ^{Note2}	mA
		P00~P01, P20~P27, P40~P41, P120	4.0V≤V _{DD} ≤5.5V -40~85°C	-	-	100	
		P130, P136, P137, P140 Total pins	4.0V≪V _{DD} ≪5.5V 85~105°C	-	-	70	mA
		(when duty cycle \leqslant 70% $^{ m Note3}$)	2.4V≤V _{DD} <4.0V	-	-	30	mA
	IOL1		1.8V≤V _{DD} <2.4V	-	-	15	mA
Low-level output		P10~P17, P30~P31, P50~P51	4.0V≤V _{DD} ≤5.5V -40~85°C	-	-	120	
current Note 1		P60~P63, P70~P75, P146, P147 Total pins	4.0V≪V _{DD} ≪5.5V 85~105°C	-	-	80	mA
		(when duty cycle \leq 70% $^{\rm Note3}$)	2.4V≤V _{DD} <4.0V	-	-	40	mA
			1.8V≤V _{DD} <2.4V	-	-	20	mA
		Total pins	1.8V≤V _{DD} ≤5.5V -40~85°C	-	-	150	
		(when duty cycle \leqslant 70% $^{ m Note3}$)	1.8V≪V _{DD} ≪5.5V 85~105°C	-	-	100	mA
		P121 ~ P124 1 pin alone	1.8V≤V _{DD} ≤5.5V	-	-	10 Note2	mA
	Iol2	Total pins (when duty cycle ≤70% ^{Note3})	1.8V≤V _{DD} ≤5.5V	-	-	40	mA

Note1: This is the current value that guarantees the operation of the device even if the current flows from the output pin to the V_{SS} pin.

Note2: Can not exceed the total current value.

Note3: This is the output current value of "duty cycle≤70% condition".

The output current value with a duty cycle> 70% can be calculated with the following calculation formula (when the duty cycle is changed to n%)

The total output current of the pins = $(IOL \times 0.7)/(n \times 0.01)$

<example> IOL= 10.0mA, n = 80%

The total output current of the pins = $(10.0 \times 0.7)/(80 \times 0.01) \approx 8.7$ mA

The current of each pin does not change due to the duty cycle, and no current above the absolute maximum rating will flow.



Item	Symbol	Condition		Min	Тур	Max	Unit
		P00~P01, P10~P17, P20~P27					
		P30~P31, P40~P41, P50~P51					
High level	V _{IH1}	P62~P63, P70~P75, P120~P124	Schmidt input	$0.8V_{DD}$	-	V_{DD}	V
input voltage		EXCLK, EXCLKS, RESETB, P130					
		P136, P137, P140, P146, P147					
	VIH2	P60~P61		$0.7V_{DD}$	-	6.0	V
		P00~P01, P10~P17, P20~P27					
		P30~P31, P40~P41, P50~P51					
High level	VIL1	P62~P63, P70~P75, P120~P124	Schmidt input	0	-	$0.2V_{\text{DD}}$	V
input voltage		EXCLK, EXCLKS, RESETB, P130					
		P136, P137, P140, P146, P147					
	VIL2	P60~P61		0	-	0.3V _{DD}	V



Item	Symbol	Condition		Min	Тур	Max	Unit
			4.0V≤V _{DD} ≤5.5V I _{OH1} =-12.0mA	V _{DD} -1.5	-	-	V
		P00~P01, P10~P17, P20~P27 P30~P31, P40~P41, P50~P51	4.0V≤V _{DD} ≤5.5V I _{OH1} =-6.0mA	V _{DD} -0.7	-	-	V
	V _{OH1}	P60~P63, P70~P75, P120, P130 P136, P137, P140, P146, P147	2.4V≤V _{DD} ≤5.5V I _{OH1} =-3.0mA	V _{DD} -0.6	-	-	V
High level output			1.8V≪V _{DD} ≪5.5V I _{OH1} =-2mA	V _{DD} -0.5	-	-	V
voltage	V _{OH2} P		4.0V≤V _{DD} ≤5.5V I _{OH2} =-2.5mA	V _{DD} -1.5	-	-	V
		P121~P124	4.0V≪V _{DD} ≪5.5V I _{0H2} =-1.5mA		-	-	V
		F 121~F 124	2.4V≤V _{DD} ≤5.5V I _{OH2} =-0.5mA	V _{DD} -0.6	-	-	V
			1.8V≤V _{DD} ≤5.5V I _{OH2} =-0.4mА	V _{DD} -0.5	-	-	V
			4.0V≤V _{DD} ≤5.5V I _{OL1} =35.0mA	-	-	1.2	V
		P00~P01, P10~P17, P20~P27 P30~P31, P40~P41, P50~P51	4.0V≤V _{DD} ≤5.5V I _{OL1} =20.0mA	-	-	0.7	V
	Vol1	P60~P63, P70~P75, P120, P130 P136, P137, P140, P146, P147	2.4V≤V _{DD} ≤5.5V I _{OL1} =9.0mA	-	-	0.4	V
Low-level			1.8V≤V _{DD} ≤5.5V I _{OL1} =6.0mA	-	-	0.4	V
output voltage			4.0V≤V _{DD} ≤5.5V I _{OL2} =10.0mA	-	-	1.2	V
			4.0V≤V _{DD} ≤5.5V I _{OL2} =6.0mA	-	-	0.7	V
	Vol2	P121~P124	2.4V≤V _{DD} ≤5.5V I _{OL2} =2.5mA	-	-	0.4	V
			1.8V≤V _{DD} ≤5.5V I _{OL2} =1.5mA	-	-	0.4	V



Item	Symbol	Condition		Min	Тур	Max	Unit
	Ішні	P00~P01, P10~P17, P20~P27 P30~P31, P40~P41, P50~P51 P60~P63, P70~P75, P120, P130 P136, P137, P140, P146, P147	VI=VDD	-	-	1	uA
	I _{LIH2}	RESETB	VI=VDD	-	-	1	uA
High-level input leakage current	Ілнз	P121~P124 (X1, X2, EXCLK, XT1	V _I =V _{DD} , when input port and external clock input	-	-	1	uA
		XT2, EXCLKS)	VI=VDD, when the resonator is connected	-	-	10	uA
	Ilil1	P00~P01, P10~P17, P20~P27 P30~P31, P40~P41, P50~P51 P60~P63, P70~P75, P120, P130 P136, P137, P140, P146, P147	VI=VSS	-	-	-1	uA
	I _{LIL2}	RESETB	VI=VSS	-	-	-1	uA
Low-level input leakage current	ILIL3	P121~P124 (X1, X2, EXCLK, XT1	V _I =V _{SS} , when input port and external clock input	-	-	-1	uA
		XT2, EXCLKS)	V _I =V _{SS} , when the resonator is connected	-	-	-10	uA
Internal pull-up resistor	Ru	P00~P01, P10~P17, P20~P27 P30~P31, P40~P41, P50~P51 P60~P63, P70~P75, P120, P130 P136, P137, P140, P146, P147	VI=Vss, when input port	10	30	100	kΩ
Internal pull- down resistor	RD	P00~P01, P10~P17, P20~P27 P30~P31, P50~P51, P60~P63 P70~P75, P120, P130, P136, P137 P140, P146, P147	VI=VDD, when input port	10	30	100	kΩ

6.5.2 Power Supply Current Characteristics

Item	Symbol		Cor	ndition		Min	Тур	Max	Unit
			High-speed internal	FHOCO=64MHz, FIH=64MHz Note3		-	4.5	6.9	mA
			oscillator	Fносо=64MHz, Fir	l=32MHz ^{Note3}	-	3.5	4.5	ШA
	Idd1		High-speed main system clock	F _{MX} =20MHz ^{Note2}	Input square wave	-	6.0	6.5	m 4
		Operating			Connect the crystal	-	6.0	6.5	mA
		mode	Subsystem clock	Fsub=32.768KHz	Input square wave	-	175	300	uA
			operation	Note4	Connect the crystal	-	175	300	uA
			Low-speed internal oscillator	FIL=15KHz Note8		-	174	300	uA
Current Note1			High-speed internal FHOCO=64MHz, FIH=64MHz Note3		-	1.7	2.6	mA	
Carlon			oscillator	Fносо=32MHz, Fir	-	1.1	1.7		
			High-speed main system clock	F _{MX} =20MHz ^{Note2}	Input square wave	-	0.85	1.3	mA
	I _{DD2}			FMX=20IVIH2 Hold2	Connecting crystal	-	0.85	1.3	mA
	JUDZ	Sleep mode	Subsystem clock	Fsub=32.768KHz	Input square wave	-	85	240 240	
			operation	Note5	Connecting crystal	-	85		uA
			Low-speed internal oscillator	Fı∟=15KHz ^{Note8}		-	85	240	uA
	DD3 Note6	Deep sleep mode ^{Note7}		-		-	80	185	uA

(T_A= -40~105°C, 1.8V≤V_{DD}≤5.5V, V_{SS}=0V)

Note1: This is the current flowing through V_{DD}, including the input leakage current when the input pin is fixed to V_{DD} or V_{SS}. Typ. Value: CPU is in the execution of multiplication instruction (I_{DD1}), And does not include peripheral operating current. Max. Value: CPU is in full instruction execution action (I_{DD1}), and includes peripheral operating current, but does not include the flow to the A/D converter. The current of the LVD circuit, I/O port, and internal pull-up or pull-down resistors does not include the current when rewriting data flash memory

- Note2: This is the case when the high-speed internal oscillator and the subsystem clock stop oscillating.
- Note3: This is the case where the high-speed main system clock and subsystem clock stop oscillating.
- Note4: This is the case when the high-speed internal oscillator and the high-speed main system clock stop oscillating.

Note5: This is the case when the high-speed internal oscillator and the high-speed main system clock



stop oscillating. Contains the current flowing to the RTC, but does not include the 15-bit interval timer and watchdog Timer current.

Note6: Does not include current to RTC, 15-bit interval timer and watchdog timer.

Note7: For the current value when the subsystem clock is running in the deep sleep mode, please refer to the current value when the subsystem clock is running in the sleep mode.

Note8: This is the case where the high-speed internal oscillator, the high-speed main system clock and the subsystem clock stop oscillating.

Remark:

- F_{HOCO}: The clock frequency of the high-speed internal oscillator
 F_{IH}: the system clock frequency provided by the high-speed internal oscillator.
- 2. F_{SUB}: External subsystem clock frequency (XT1/XT2 clock oscillation frequency).
- 3. F_{MX}: External main system clock frequency (X1/X2 clock oscillation frequency).
- 4. F_{IL}: Clock frequency of low-speed internal oscillator.
- 5. Typ. The temperature condition of the value is $T_A=25$ °C.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Low-speed internal oscillator	FIL ^{Note1}			0.2		uA
operating current	IFIL	-	-	0.2	-	uA
RTC operating current	RTC ^{Note1,2,3}	-	-	0.04	-	uA
15-bit interval timer operating	IT-Note1,2,4		_	0.02	-	uA
current		-	-			uA
Watchdog timer operating current	WDT ^{Note1,2,5}	Fı∟=15KHz	-	0.22	-	uA
A/D converter operating current	I _{ADC} Note1,6	ADC @8MHz	-	2.2	-	mA
LVD operating current	LVD ^{Note1,7}	-	-	0.08	-	uA

Note1: This is the current flowing through VDD.

- Note2: This is the case when the high-speed internal oscillator and the high-speed system clock stop oscillating.
- Note3: This is the current that only flows to the real-time clock (RTC) (not including the operating current of the low-speed internal oscillator and XT1 oscillator circuit). When the real-time clock is running in running mode or sleep mode, the current value of the microcontroller is I_{DD1} or I_{DD2} plus the value of I_{RTC}. In addition, when low-speed internal oscillator is selected, I_{FIL} must be added. I_{DD2} when the subsystem clock is running contains the operating current of the real-time clock.
- Note4: This is the current that only flows to the 15-bit interval timer (not including the operating current of the low-speed internal oscillator and XT1 oscillator circuit). When the 15-bit interval timer is running in run mode or sleep mode, the current value of the microcontroller is the value of I_{DD1} or I_{DD2} plus IIT. In addition, when low-speed internal oscillator is selected, I_{FIL} must be added.
- Note5: This is the current that only flows to the watchdog timer (including the operating current of the lowspeed internal oscillator). When the watchdog timer is running, the current value of the microcontroller is I_{DD1} or I_{DD2} or I_{DD3} plus the value of I_{WDT}.
- Note6: This is the current that only flows to the A/D converter. When the A/D converter is running in running mode or sleep mode, the current value of the microcontroller is I_{DD1} or I_{DD2} plus the value of I_{ADC}.
- Note7: This is the current that only flows to the LVD circuit. In the case of LVD circuit operation, the current value of the microcontroller is the value of I_{DD1} or I_{DD2} or I_{DD3} plus I_{LVD}.

Remark:

- 1. FIL: Clock frequency of low-speed internal oscillator.
- 2. Typ. The temperature condition of the value is $T_A=25$ °C.



6.6 AC Characteristic

(I _A = -40~105 C, 1.8V≤V _{DD} ≤5.5V, V _{SS} =0V)										
Item	Symbol	Conditi	on	Min	Тур	Max	Unit			
Instruction cycle		The main system clock	1.8V≪V _{DD} ≪5.5V	0.015625	_	0.5	us			
(Minimum	Тсү	(F _{MAIN}) runs	1.6V < VDD < 5.5V	0.015625	-	0.5	us			
instruction execution time)	TCY	Subsystem clock (F _{SUB}) operation	1.8V≤V _{DD} ≤5.5V	28.5	30.5	31.3	us			
External system	F _{EX}	1.8V≤V _{DD} ≤5.5V		1.0	-	20.0	MHz			
clock frequency	F _{EXS}	1.8V≤V _{DD} ≤5.5V		32.0	-	35.0	KHz			
High and low level width of external T_{EXH} T_{EXL} $1.8V \leq V_{DD} \leq 5.5V$				24	-	-	ns			
system clock input	T _{EXHS} T _{EXLS}	1.8V≪V _{DD} ≪5.5V	13.7	-	-	us				
TI00 ~TI03, TI10 ~TI13, input high and low level width	Ттін Тті∟	1.8V≪V _{DD} ≪5.5V	1/Fмск +10	-	-	ns				
TO00 ~ TO03		$4.0V \leq V_{DD} \leq 5.5V$	1.0V≤V _{DD} ≤5.5V		-	16	MHz			
TO10 ~ TO13	Fто	2.4V≤V _{DD} <4.0V		-	-	8	MHz			
output frequency		1.8V≤V _{DD} <2.4V		-	-	4	MHz			
CLKBUZ0,		4.0V≤V _{DD} ≤5.5V		-	-	16	MHz			
CLKBUZ1	F _{PCL}	2.4V≤V _{DD} <4.0V		-	-	8	MHz			
Output frequency		1.8V≤V _{DD} <2.4V		-	-	4	MHz			
Interrupt input high and low level width	Tinth Tintl	INTP0 ~ INTP3	1.8V≪V _{DD} ≪5.5V	1	-	-	us			
Key interrupt input high and low level width	Tĸĸ	KR0 ~ KR5	1.8V≪V _{DD} ≪5.5V	250	-	-	ns			
RESETB low-level width	T _{RSL}	-		10	-	-	-			

(T_A= -40~105°C, 1.8V≤V_{DD}≤5.5V, V_{SS}=0V)

Remark: F_{MCK} : Operating clock frequency of timer4 unit.



6.7 Peripheral Features

6.7.1 Universal Interface Unit

1) UART mode

(T_A= -40~85°C, 1.8V≤V_{DD}≤5.5V, V_{SS}=0V)

Item Condition		Condition	Specific	Unit	
		Condition	Min	Max	Unit
	-		F мск/6	bps	
Transfer rate	$\label{eq:transfer} Transfer \ rate \qquad 1.8V \leqslant V_{DD} \leqslant 5.5V$	The theoretical value of the maximum		10.6	Mhoo
		transfer rate F _{MCK} =F _{CLK}	-	10.6	Mbps

(T_A= -40~85°C, 1.8V≤V_{DD}≤5.5V, V_{SS}=0V)

ltem		Condition	Specific	Unit		
nem		Condition	Min	Max	Onit	
		-	-	Fмск/12	bps	
Transfer rate	$\label{eq:transfer} Transfer \ rate \qquad 1.8V \leqslant V_{DD} \leqslant 5.5V$	Theoretical value of the maximum		5.3	Mbpc	
		transfer rate $F_{MCK} = F_{CLK}$	-	5.5	Mbps	



,		C, 1.8V≤VDD≤		-40~85	°C	85~105°	C	
Item	Symbol	C	ondition	Min	Max	Min	Max	Unit
		Тксү1 ≥ 2/fс∟к	$4.0V \leqslant V_{DD} \leqslant 5.5V$	31.25	-	62.5	-	ns
SCLKp	T		$2.7V \leqslant V_{DD} \leqslant 5.5V$	41.67	-	83.33	-	
cycle time	TKCY1	$ KCY \leq 2/ CLK $	$2.4V \leqslant V_{DD} \leqslant 5.5V$	65	-	125	-	ns
			$1.8V \leqslant V_{DD} \leqslant 5.5V$	125	-	250	-	ns
		$4.0V \leq V_{DD} \leq 5$	5.5V	Тксү1/2-4	-	Тксү1/2-7	-	ns
SCLKp	Ткн1,	$2.7 \textrm{V} \leqslant \textrm{V}_{\textrm{DD}} \leqslant 5.5 \textrm{V}$		T _{KCY1} /2-5	-	T _{KCY1} /2-10	-	ns
high/low level width	T _{KL1}	$2.4V \leqslant V_{DD} \leqslant 5.5V$		T _{KCY1} /2-10	-	T _{KCY1} /2-20	-	ns
	level width	$1.8V \leqslant V_{DD} \leqslant 5.5V$		Тксү1/2-19	-	Тксү1/2-38	-	ns
SDIp		$4.0V \leq V_{DD} \leq 5$	5.5V	12	-	23	-	ns
preparatio	T _{SIK1}	$2.7V \leq V_{DD} \leq 5$	5.5V	17	-	33	-	ns
n time (to	I SIK1	$2.4V \leqslant V_{DD} \leqslant 8$	5.5V	20	-	38	-	ns
SCLKp↑)		$1.8V \leq V_{DD} \leq 5$	5.5V	28	-	55	-	ns
SDIp hold								
time (to	TKSI1	$1.8V \leq V_{DD} \leq 5$	5.5V	5	-	10	-	ns
SCLKp↑)								
$SCLKp{\downarrow}{\rightarrow}$								
SDOp	T _{KSO1}	$1.8V \leq V_{DD} \leq 5$	5.5V	_	5	-	10	ns
output	1 601	C=20pF Note1		_	5	_	10	113
delay time								

2) Three-wire SPI mode (master mode, internal clock output)

(T_A= -40~105°C, 1.8V≤V_{DD}≤5.5V, V_{SS}=0V)

Note1: C is the load capacitance of the SCLKp and SDOp output lines.

Caution: Through the port inputmode register and the port outputmode register, the SDIp pin is selected as the normal input buffer and theSDOp the pin and SCLKp pin are selected as the usual output mode.

Remark: Guaranteed by design, not tested in production.



3)	Three-wire SPI mode (slave mode, external clock input)
----	--

, , , , , , , , , , , , , , , , , , ,		2, 1.8V ≷ VDD ≷	Condition		5°C	85 ~ 105	5°C	1.1
Item	Symbol	Cor	ndition	Min	Max	Min	Max	Unit
		$4.0V \leqslant V_{DD}$	20MHz <f<sub>MCK</f<sub>	8/ Fмск	-	16/ Ғмск	-	ns
		≤ 5.5V	F _{MCK} ≪20MHz	6/ F _{MCK}	-	12/ F _{MCK}	-	ns
		$2.7V \leq V_{DD}$	16MHz <f<sub>MCK</f<sub>	8/ F _{MCK}	-	16/ F _{MCK}	-	ns
SCLKp cycle	T _{KCY2}	$\leq 5.5 V$	F _{MCK} ≪16MHz	6/ F _{MCK}	-	12/ F _{MCK}	-	ns
time	I KCY2	$2.4V \leq V_{DD} \leq$	5.5V	6/ F _{мск} and ≥500	-	12/ F _{MCK} and ≥1000	-	ns
		$1.8V \leq V_{DD} \leq$	$1.8V \leqslant V_{DD} \leqslant 5.5V$		-	12/ F _{MCK} and ≥1500	-	ns
SCLKp	-	$4.0V \leq V_{DD} \leq$	$.0V \leq V_{DD} \leq 5.5V$		-	Тксү1/2-14	-	ns
high/low	Ткн2 т	$2.7V \leqslant V_{DD} \leqslant 5.5V$		T _{KCY1} /2-8	-	T _{KCY1} /2-16	-	ns
level width	T _{KL2}	$1.8V \leq V_{DD} \leq$	5.5V	T _{KCY1} /2-18	-	T _{KCY1} /2-36	-	ns
SDIp		$2.7V \leq V_{DD} \leq$	5.5V	1/ F _{MCK} +20	-	1/ F _{MCK} +40	-	ns
preparation time (to SCLKp↑)	preparation time (to		$1.8V \leq V_{DD} \leq 5.5V$		-	1/ F _{мск} +60	-	ns
SDIp hold time (to SCLKp↑)	Tĸsi2	$1.8V \leq V_{DD} \leq$	5.5V	1/ F _{мск} +31	-	1/ F _{мск} +62	-	ns
SCLKp↓→S		$2.7V \le V_{DD} \le C=30 pF^{Note1}$	5.5V	-	2/ F _{мск} +44	-	2/ F _{мск} +66	ns
DOp output delay	. TKSO2		5.5V	-	2/ F _{мск} +75	-	2/ F _{мск} +113	ns
time		$1.8V \leq V_{DD} \leq C=30pF^{Note1}$	§ 5.5V	-	2/ F _{MCK} +100	-	2/ F _{мск} +150	ns

Note1: C is the load capacitance of the SCLKp and SDOp output lines.

Caution: Through the port inputmode register and the port outputmode register, select the SDIp pin and SCLKp pin as the normal input buffer and select the SDOp pin as the normal output mode. Remark: Guaranteed by design, not tested in production.



4)	Four-wire	SPI mode	(slave mode,	external	clock input)
----	-----------	----------	--------------	----------	--------------

ltom	Symbol	Condition		-40~85°C		85~105°C		unit
Item	Symbol			Min	Max	Min	Max	unit
SSI00 set up		DADmn_0	$2.7V \leqslant V_{DD} \leqslant 5.5V$	120	-	240	-	ns
	Tssik	DAPmn=0	$1.8V \leqslant V_{DD} \leqslant 5.5V$	200	-	400	-	ns
	ISSIK	DAPmn=1	$2.7V \leqslant V_{DD} \leqslant 5.5V$	1/F _{MCK} +120	-	1/F _{MCK} +240	-	ns
			$1.8V \leqslant V_{DD} \leqslant 5.5V$	1/F _{MCK} +200	-	1/F _{MCK} +400	-	ns
		DAPmn=0	$2.7V \leqslant V_{DD} \leqslant 5.5V$	1/Fмск+120	-	1/F _{мск} +240	-	ns
SSI00 hold	Turan		$1.8V \leqslant V_{DD} \leqslant 5.5V$	1/F _{MCK} +200	-	1/F _{MCK} +400	-	ns
time	IKSSI	TKSSI DAPmn=1	$2.7V \leqslant V_{DD} \leqslant 5.5V$	120	-	240	-	ns
			$1.8V \leqslant V_{DD} \leqslant 5.5V$	200	-	400	-	ns

Caution: Through the port inputmode register and the port outputmode register, select the SDIp pin and SCLKp pin as the normal input buffer and select the SDOp pin as the normal outputmode. Remark: Guaranteed by design, not tested in production.



5) Simple IIC mode

(T_A= -40~105°C, 1.8V≤V_{DD}≤5.5V, V_{SS}=0V)

, i i i i i i i i i i i i i i i i i i i			-40~8	5°C	85~105	11.2	
Item	Symbol	Condition	Min	Max	Min	Max	Unit
		$\label{eq:DD} \begin{array}{l} 2.7 V \leqslant V_{DD} \leqslant 5.5 V \\ C_{b} = 50 \; pF, \; R_{b} = 2.7 \; k\Omega \end{array}$	-	1000 Note1	-	400 Note1	KHz
SCLr Clock frequency	Fscl	$\label{eq:VDD} \begin{split} 1.8 V &\leqslant V_{DD} \leqslant 5.5 V \\ C_{b} = 100 \; pF, R_{b} = 3 \; k \Omega \end{split}$	-	400 Note1	-	100 ^{Note1}	KHz
		$\label{eq:def_def_def} \begin{split} 1.8 V \leqslant V_{DD} \leqslant 2.7 V \\ C_b = 100 \text{ pF}, \text{R}_b = 5 \text{k} \Omega \end{split}$	-	300 Note1	-	75 Note1	KHz
Hold time when SCLr is T _{LOW} low	$\begin{array}{l} 2.7 V \leqslant V_{DD} \leqslant 5.5 V \\ C_{b} = 50 \; pF, R_{b} = 2.7 \; k\Omega \end{array}$	475	-	1200	-	ns	
	TLOW	$\label{eq:def_def_def} \begin{split} 1.8 V \leqslant V_{DD} \leqslant 5.5 V \\ C_b = 100 \text{ pF}, \text{R}_b = 3 \text{k} \Omega \end{split}$	1150	-	4600	-	ns
		$\label{eq:VDD} \begin{split} 1.8 V \leqslant V_{DD} \leqslant 2.7 V \\ C_b = 100 \text{ pF}, \text{ R}_b = 5 \text{ k}\Omega \end{split}$	1550	-	6500	-	ns
Hold time when SCLr is		$\begin{array}{l} 2.7 V \leqslant V_{DD} \leqslant 5.5 V \\ C_{b} = 50 \; pF, R_{b} = 2.7 \; k\Omega \end{array}$	475	-	1200	-	ns
	Тнідн	$\label{eq:def_def_def} \begin{split} 1.8 V \leqslant V_{DD} \leqslant 5.5 V \\ C_b = 100 \text{ pF}, \text{ R}_b = 3 \text{ k} \Omega \end{split}$	1150	-	4600	-	ns
high		$\label{eq:def_def_def} \begin{split} 1.8 V \leqslant V_{DD} \leqslant 2.7 V \\ C_b = 100 \text{ pF}, \text{R}_b = 5 \text{k} \Omega \end{split}$	1550	-	6500	-	ns
Dete		$\begin{array}{l} 2.7 V \leqslant V_{DD} \leqslant 5.5 V \\ C_{b} = 50 \; pF, R_{b} = 2.7 \; k\Omega \end{array}$	1/F _{MCK} +85 _{Note2}	-	1/F _{MCK} +220 Note2	-	ns
Data establishment	TSU: DAT	$\label{eq:def_def_def} \begin{split} 1.8 V \leqslant V_{DD} \leqslant 5.5 V \\ C_b = 100 \text{ pF}, \text{ R}_b = 3 \text{ k}\Omega \end{split}$	1/F _{MCK} +145 _{Note2}	-	1/F _{MCK} +580 _{Note2}	-	ns
time (received)		$\label{eq:def_def_def} \begin{split} 1.8 V \leqslant V_{DD} \leqslant 2.7 V \\ C_b = 100 \text{ pF}, \text{ R}_b = 5 \text{ k}\Omega \end{split}$	1/F _{MCK} +230 _{Note2}	-	1/F _{MCK} +1200 _{Note2}	-	ns
		$\begin{array}{l} 2.7 V \leqslant V_{DD} \leqslant 5.5 V \\ C_{b} = 50 \; pF, R_{b} = 2.7 \; k\Omega \end{array}$	-	305	-	770	ns
Data retention time (send)	THD: DAT	$\label{eq:VDD} \begin{split} 1.8 V \leqslant V_{DD} \leqslant 5.5 V \\ C_{b} = 100 \; pF, R_{b} = 3 \; k \Omega \end{split}$	-	355	-	1420	ns
		$\label{eq:VDD} \begin{array}{l} 1.8 V \leqslant V_{DD} \leqslant 2.7 V \\ C_{b} = 100 \; pF, R_{b} = 5 \; k \Omega \end{array}$	-	405	-	2070	ns

Note1: Must be set to at least $F_{MCK}/4$.

Note2: The set value of F_{MCK} cannot exceed the holding time of SCLr="L" and SCLr="H".

6.7.2 Serial Interface IICA

1) I²C standard mode

(T_A= -40~105°C, 1.8V≤V_{DD}≤5.5V, V_{SS}=0V)

	0 1 1		Specificat	1 Jun 14	
Item	Symbol	Condition	Min	Max	Unit
SCLA0 clock frequency	Fsc∟	Standard mode: F _{CLK} ≥1MHz	-	100	KHz
Start condition set up time	T _{SU:} STA	-	4.7	-	us
Start condition hold time Note1	THD: STA	-	4.0	-	us
Hold time when SCLA0 is low	T _{LOW}	-	4.7	-	us
Hold time when SCLA0 is high	Тнідн	-	4.0	-	us
Data establishment time (received)	TSU: DAT	-	250	-	ns
Data retention time (send) Note2	THD: DAT	-	0	3.45	us
Stop condition set up time	Tsu⊧ sto	-	4.0	-	us
Bus idle time	T _{BUF}	-	4.7	-	us

Note1: Generate the first clock pulse after generating the start condition or restarting the condition.

Note2: During normal transmission, tHD: the maximum value of DAT (Max.) needs to be guaranteed, and it is necessary to wait for an acknowledgement (ACK).

Remark: The Max. value of C_b (communication line capacitance) of each mode and the value of R_b (communication line pull-up resistance value) at this time are as follows:

Standard mode: Cb=400pF, Rb=2.7k\Omega

2) I²C fast mode

(T_A= -40~105°C, 1.8V≤V_{DD}≤5.5V, V_{SS}=0V)

ltom	Symbol	Condition	Specificat	Unit	
Item	Symbol	Condition	Min	Max	Unit
SCLA0 clock frequency	F _{SCL}	Fast mode: F _{CLK} ≥3.5MHz	-	400	KHz
Start condition set up time	TSU: STA	-	0.6	-	us
Start condition hold time Note1	THD: STA	-	0.6	-	us
Hold when SCLA0 is low time	TLOW	-	1.3	-	us
Hold when SCLA0 is high time	Тнідн	-	0.6	-	us
Data set up time (received)	TSU: DAT	-	100	-	ns
Data hold time (send) Note2	THD: DAT	-	0	0.9	us
Stop condition set up time	T _{SU:} STO	-	0.6	-	us
Bus idle time	T _{BUF}	-	1.3	-	us

Note1: Generate the first clock pulse after generating the start condition or restarting the condition.

Note2: During normal transmission, t_{HD}: the maximum value of DAT (Max.) needs to be guaranteed, and it is necessary to wait for an acknowledgement (ACK).

Remark: The Max. value of C_b (communication line capacitance) of each mode and the value of R_b (communication line pull-up resistance value) at this time are as follows: Fast mode: $C_b=320pF$, $R_b=1.1k\Omega$



3) I²C enhanced fast mode

(T_A= -40~105°C, 1.8V≪V_{DD}≪5.5V, V_{SS}=0V)

Item	Symbol Condition		Specificat	tion Value	Unit
nem	Symbol	Condition	Min	Max	Unit
SCLA0 clock frequency	Fscl	Enhanced fast mode: F _{CLK} ≥10MHz	-	1000	KHz
Start condition set up time	T _{SU: STA}	-	0.26	-	us
Start condition hold time Note1	T _{HD: STA}	-	0.26	-	us
Hold time when SCLA0 is low	T _{LOW}	-	0.5	-	us
When SCLA0 is high hold time	Thigh	-	0.26	-	us
Data set up time (received)	T _{SU: DAT}	-	50	-	ns
Data hold time (send) Note2	T _{HD: DAT}	-	0	0.45	us
Stop condition set up time	Tsu: sto	-	0.26	-	us
Bus idle time	T _{BUF}	-	0.5	-	us

Note1: Generate the first clock pulse after generating the start condition or restarting the condition.

Note2: During normal transmission, t_{HD}: the maximum value of DAT (Max.) needs to be guaranteed, and it is necessary to wait for an acknowledgement (ACK).

Remark: The Max.value of C_b (communication line capacitance) of each mode and the value of R_b (communication line pull-up resistance value) at this time are as follows:

Enhanced fast mode: $C_b=120pF$, $R_b=1.1K\Omega$



6.8 Analog Characteristic

6.8.1 A/D Converter Characteristic

The distinction of A/D converter characteristic

R Input channel	eference voltage	Reference voltage (+) = V _{DD} Reference voltage (-) =V _{SS}
ANI0~ANI36		Defense to the table balance
Internal reference voltage, output voltage of	temperature sensor	Refer to the table below

Select the case of reference voltage(+)= V_DD, reference voltage(-)= V_SS

(T_A= -40~105°C, 1.8V≤V_{DD}≤5.5V, V_{SS}=0V, reference voltage(+)=V_{DD}, reference voltage(-)=V_{SS})

Item	Symbol	Conditi	on	Min	Тур	Max	Unit
Resolution	RES	-	-			-	bit
Composite error	AINL	12-bit resolution	1.8V≤V _{DD} ≤5.5V	-	6	-	LSB
Conversion time	T _{CONV}	12-bit resolution Conversion target: ANI0~ANI36	1.8V≤V _{DD} ≤5.5V	16	-	-	Tmclk
Zero error Note1	Ezs	12-bit resolution	1.8V≪V _{DD} ≪5.5V	-	0	-	LSB
Full scale error	E _{FS}	12-bit resolution	1.8V≪V _{DD} ≪5.5V	-	0	-	LSB
Integral linearity error Note1	ILE	12-bit resolution	1.8V≤V _{DD} ≤5.5V	-	-	±2	LSB
Differential linearity error Note1	DLE	12-bit resolution	1.8V≤V _{DD} ≤5.5V	-	-	±3	LSB
		ANI0~ANI36		0	-	Vdd	V
Analog input	V _{AIN}	Internal reference voltage (1.8V≪V _{DD} ≪5.5V)		V_{BGR} Note2		V
voltage	* AIN	The output voltage of the te (1.8V≪V _{DD} ≪5.5V)	V	TMPS25 Note2	2	V	

Note1: Does not include quantization error (±1/2 LSB).

Note2: "6.8.2 Characteristic of Temperature Sensor/Internal Reference Voltage"

Note3: Tmclk is the AD action clock cycle, the maximum action frequency is 8MHz.

Remark: Guaranteed by design, not tested in production.

6.8.2 Characteristic of Temperature Sensor/Internal Reference

Voltage

Item	Symbol	Condition	Min	Тур	Max	Unit
The output voltage of the temperature sensor	V _{TMPS25}	T _A =25°C	-	1.09	-	V
Internal reference voltage	VBGR	-	1.38 ^{Note1}	1.45	1.5 ^{Note1}	V
Temperature Coefficient	F _{VTMPS}	-	-	-3.5	-	mV/°C
Stable operation waiting time	T _{AMP}	-	5	-	-	us

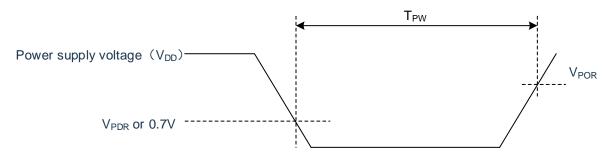
Note1: Low temperature Specification Value is guaranteed by design, mass production does not measure low temperature conditions.

6.8.3 POR Circuit Characteristic

(T _A = -40~105°C, V _{SS} =0V)	/)	Vss=0V	°C.	105	-40~	(T _A =	(
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Item Sym		Condition	Min	Тур	Max	Unit
Detection voltage	VPOR	When the power supply voltage rises	-	1.50	1.75	V
Detection voltage	VPDR	When the power supply voltage drops	1.37	1.45	-	V
Minimum pulse width ^{Note1}	T _{PW}	-	300	-	-	us

Note1: This is the time required for POR to reset when V_{DD} is lower than V_{PDR}. In addition, in the deep sleep mode, when the main system clock (F_{MAIN}) is stopped by setting bit0 (HIOSTOP) and bit7 (MSTOP) of the clock operation status control register (CSC), the oscillation of the main system clock (F_{MAIN}) is stopped from V_{DD} lower than 0.7V to rise above V_{POR}. Time required for POR reset.





6.8.4 LVD Circuit Characteristic

1) Reset mode, interrupt mode

(T_A= -40~105°C, V_{PDR}≤V_{DD}≤5.5V, V_{SS}=0V)

Item	Symbol	Condition	Min	Тур	Max	Unit
	M	power supply voltage rises	-	4.06	4.14	V
	VLVD0	power supply voltage drops	3.90	3.98	-	V
	M	power supply voltage rises	-	3.75	-	V
	V _{LVD1}	power supply voltage drops	-	3.67	-	V
	M	power supply voltage rises	-	3.13	-	V
	V _{LVD2}	power supply voltage drops	-	3.06	-	V
	M	power supply voltage rises	-	3.02	-	V
	V _{LVD3}	power supply voltage drops	-	2.96	-	V
	M	power supply voltage rises	-	2.92	-	V
Detection voltage	V _{LVD4}	power supply voltage drops	-	2.86	-	V
	V _{LVD5}	power supply voltage rises	-	2.81	-	V
		power supply voltage drops	-	2.75	-	V
	V_{LVD6}	power supply voltage rises	-	2.71	-	V
		power supply voltage drops	-	2.65	-	V
	M	power supply voltage rises	-	2.61	-	V
	V _{LVD7}	power supply voltage drops	-	2.55	-	V
	M	power supply voltage rises	-	2.50	-	V
	V _{LVD8}	power supply voltage drops	-	2.45	-	V
	M	power supply voltage rises	-	2.09	-	V
	V _{LVD9}	power supply voltage drops	-	2.04	-	V
		power supply voltage rises	-	1.98	-	V
	VLVD10	power supply voltage drops	-	1.94	-	V
	Maria	power supply voltage rises	-	1.88	1.91	V
	VLVD11	power supply voltage drops	1.80	1.84	-	V
Minimum pulse width	T _{LW}	-	300	-	-	us
Detection delay	-	-	-	-	300	us



2) Interrupt & reset mode

 $(T_{A}=-40\sim105^{\circ}C, V_{PDR} \leq V_{DD} \leq 5.5V, V_{SS}=0V)$

Item	Symbol	Сог	ndition	Min	Тур	Max	Unit
	VLVDA0	VPOC2, VPOC1, VPOC0=0, 0, 0	, Falling reset voltage	1.60	1.63	-	V
	Maria	LVIS1, LVIS0=1, 0	rising reset release voltage	-	1.77	1.81	V
	VLVDA1	LVIST, LVISO=1, 0	drop interrupt voltage	1.70	1.73	-	V
	VLVDA2	LVIS1, LVIS0=0, 1	rising reset release voltage	-	1.88	-	V
	V LVDA2	LVIST, LVISO=0, T	drop interrupt voltage	-	1.84	-	V
	V _{LVDA3}	LVIS1, LVIS0=0, 0	rising reset release voltage	-	2.92	-	V
	V LVDA3		drop interrupt voltage	-	2.86	-	V
	VLVDB0	VPOC2, VPOC1, VPOC0=0, 0, 1	, decrease reset voltage	-	1.84	-	V
	VLVDB1	LVIS1, LVIS0=1, 0	rising reset release voltage	-	1.98	-	V
	VLVDBI	20101, 20100-1, 0	drop interrupt voltage	-	1.94	-	V
	VLVDB2	LVIS1, LVIS0=0, 1	rising reset release voltage	-	2.09	-	V
Interrupt & reset		20101, 20100-0, 1	drop interrupt voltage	-	2.04	-	V
	V _{LVDB3}	LVIS1, LVIS0=0, 0	rising reset release voltage	-	3.13	-	V
	V LVDB3	2001, 2000-0, 0	drop interrupt voltage	-	3.06	-	V
mode	V _{LVDC0}	VPOC2, VPOC1, VPOC0=0, 1, 0	-	2.45	-	V	
	VLVDC1	LVIS1, LVIS0=1, 0	rising reset release voltage	-	2.61	-	V
	VLVDCT	20101, 20100-1, 0	drop interrupt voltage	-	2.55	-	V
	VINDOR	LVIS1, LVIS0=0, 1	rising reset release voltage	-	2.71	-	V
	VLVDC2	20101, 20100-0, 1	drop interrupt voltage	-	2.65	-	V
	VLVDC3	LVIS1, LVIS0=0, 0	rising reset release voltage	-	3.75	-	V
	V LVDC3		drop interrupt voltage	-	3.67	-	V
	VLVDD0	VPOC2, VPOC1, VPOC0=0, 1, 1	, decrease reset voltage	-	2.75	-	V
	VLVDD1	LVIS1, LVIS0=1, 0	rising reset release voltage	-	2.92	-	V
	V LVDD1		drop interrupt voltage	-	2.86	-	V
	VLVDD2	LVIS1, LVIS0=0, 1	rising reset release voltage	-	3.02	-	V
			drop interrupt voltage	-	2.96	-	V
	V _{LVDD3}	LVIS1, LVIS0=0, 0	rising reset release voltage	-	4.06	4.14	V
	V LVDD3		drop interrupt voltage	3.90	3.98	-	V

6.8.5 Reset Time and Rising Slope of The Power Supply

Voltage

(T_A= -40~105°C, V_{SS}=0V)

Item	Symbol	Condition	Min	Тур	Max	Unit
Reset time	Treset	-	-	1	-	ms
The rising slope of the power supply voltage	SVDD	-	-	-	54	V/ms



6.9 Memory Characteristic

6.9.1 Flash Memory

Symbol	Parameter	Conditions	Min	Max	Unit
T_{PROG} Word Program (32bit) $T_{A=}$ -40~105°C		T _A = -40~105°C	-	120	us
T _{ERASE} Sector erase Chip erase	Sector erase	T _A = -40~105°C	2	3	ms
	Chip erase	T _A = -40~105°C	30	40	ms
Nend	Endurance	T _A = -40~105°C	100	-	Kcycle
T _{RET}	Data retention	100 kcycle ^{Note1} at T _A = 105°C	20	-	Years

(T_A= -40~105°C, 1.8V≤V_{DD}≤5.5V, V_{SS}=0V)

Note1: Guaranteed by design, not tested in production.

Remark: Cycling performed over the whole temperature range.

6.9.2 RAM Memory

Symbol	Parameter	Conditions	Min	Max	Unit
Vramhold	RAM Hold Voltage	T _A = -40∼105°C	0.8	-	V



6.10 EMS

6.10.1 Electrostatic Discharge (ESD)

Symbol	Parameter	Conditions	Class	
V _{ESD1(HBM)} ^{Note1}	Electrostatic discharge voltage	$T_A = 25^{\circ}C$	ЗA	
VESD1(HBM)	(human body model)	conforming to JESD22-A114	SA	
VNote2	Electrostatic discharge voltage	$T_A = 25^{\circ}C$	1.0	
VESD2(HBM) ^{Note2}	(human body model)	conforming to JESD22-A114	1A	

Note1: HBM performance of IO pins except RESETB, P60 and P61.

Note2: HBM performance of RESETB, P60 and P61 IO.

Remark 1: Guaranteed by design, not tested in production.

6.10.2 Static Latch-up(LU)

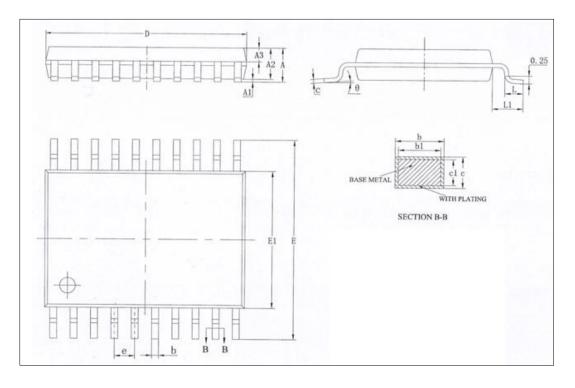
Symbol	Parameter	Conditions	Class
LU	Static latch-up class	$T_A = 25^{\circ}C$ conforming to JESD78E	I LevelA

Remark: Guaranteed by design, not tested in production.



7 Package Information

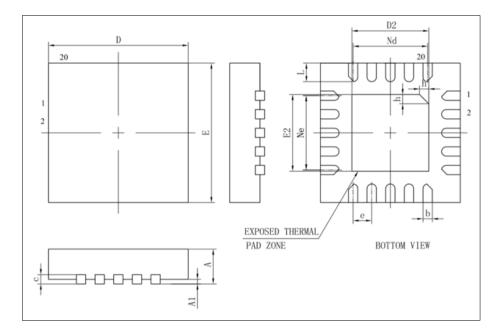
7.1 TSSOP20 (6.5x4.4mm, 0.65mm spacing)



Currente al		Millimeter		
Symbol —	Min	Nom	Мах	
A	-	-	1.20	
A1	0.05	-	0.15	
A2	0.80	1.00	1.05	
A3	0.39	0.44	0.49	
b	0.20	-	0.28	
b1	0.19	0.22	0.25	
с	0.13	-	0.17	
c1	0.12	0.13	0.14	
D	6.40	6.50	6.60	
E1	4.30	4.40	4.50	
E	6.20	6.40	6.60	
е		0.65BSC		
L	0.45	0.60	0.75	
L1	1.00REF			
θ	0	-	8°	



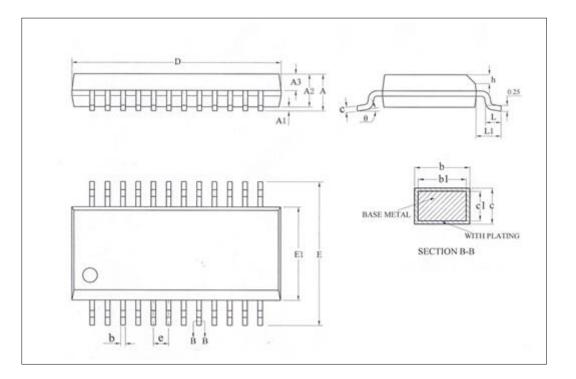
7.2 QFN20 (3x3mm, 0.4mm spacing)



Querrale		Millimeter		
Symbol	Min	Nom	Max	
А	0.70	0.75	0.80	
A1	-	0.02	0.05	
b	0.15	0.20	0.25	
С	0.18	0.20	0.25	
D	2.90	3.00	3.10	
D2	1.55	1.65	1.75	
е	0.40BSC			
Ne	1.60BSC			
Nd		1.60BSC		
E	2.90	3.00	3.10	
E2	1.55	1.65	1.75	
L	0.35	0.40	0.45	
h	0.20	0.25	0.30	



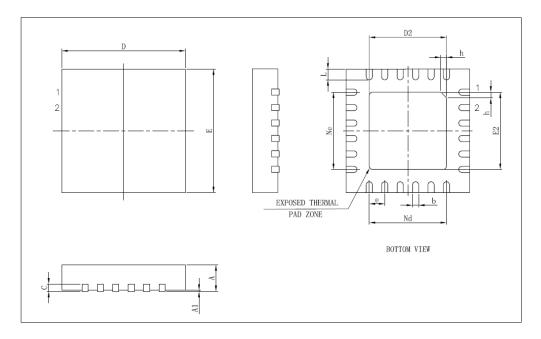
7.3 SSOP24 (8.65x3.9mm, 0.635mm spacing)



Querra la cal		Millimeter		
Symbol	Min	Nom	Max	
A	-	-	1.75	
A1	0.10	0.15	0.25	
A2	1.30	1.40	1.50	
A3	0.60	0.65	0.70	
b	0.23	-	0.31	
b1	0.22	0.25	0.28	
С	0.20	-	0.24	
c1	0.19	0.20	0.21	
D	8.55	8.65	8.75	
E1	3.80	3.90	4.00	
E	5.80	6.00	6.20	
е		0.635BSC		
h	0.30	-	0.50	
L	0.50	-	0.80	
L1	1.05REF			
θ	0	-	8°	



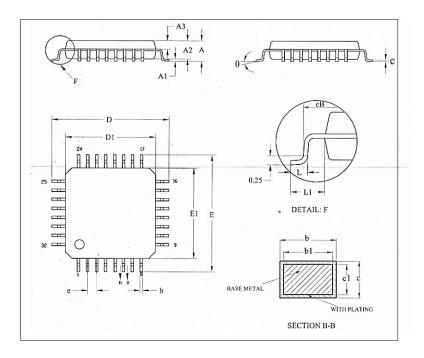
7.4 QFN24 (4x4mm, 0.5mm spacing)



Querra la cl		Millimeter		
Symbol	Min	Nom	Max	
А	0.70	0.75	0.80	
A1	-	0.02	0.05	
b	0.18	0.25	0.30	
С	0.18	0.20	0.25	
D	3.90	4.00	4.10	
D2	2.40	2.50	2.60	
е	0.50BSC			
Ne	2.50BSC			
Nd		2.50BSC		
E	3.90	4.00	4.10	
E2	2.40	2.50	2.60	
L	0.35	0.40	0.45	
h	0.30	0.35	0.40	



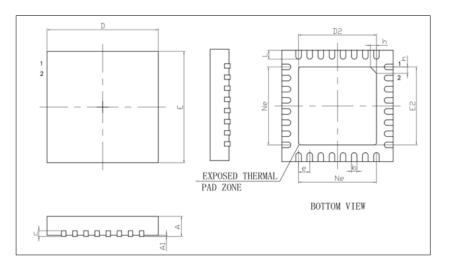
7.5 LQFP32 (7x7mm,0.8mm spacing)



Symbol		Millimeter		
Symbol	Min	Nom	Max	
А	-	-	1.60	
A1	0.05	-	0.15	
A2	1.35	1.40	1.45	
A3	0.59	0.64	0.69	
b	0.33	-	0.41	
b1	0.32	0.35	0.38	
с	0.13	-	0.17	
c1	0.12	0.13	0.14	
D	8.80	9.00	9.20	
D1	6.90	7.00	7.10	
E	8.80	9.00	9.20	
E1	6.90	7.00	7.10	
eB	8.10	-	8.25	
е		0.80BSC		
L	0.45	-	0.75	
L1	1.00REF			
θ	0°	-	7°	



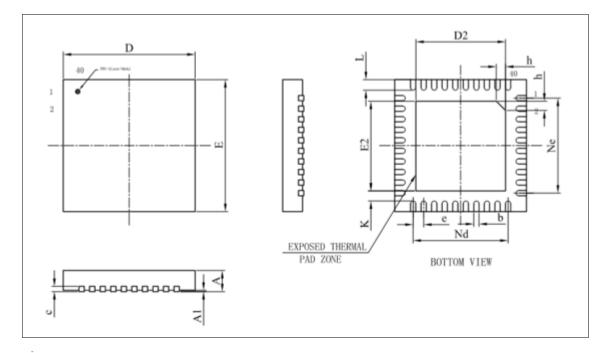
7.6 QFN32 (5x5mm, 0.5mm spacing)



Symbol		Millimeter	
Symbol	Min	Nom	Мах
A	0.70	0.75	0.80
A1	-	0.02	0.05
b	0.18	0.25	0.30
с	0.18	0.20	0.25
D	4.90	5.00	5.10
D2	3.40	3.50	3.60
е		0.50BSC	
Ne		3.50BSC	
E	4.90	5.00	5.10
E2	3.40	3.50	3.60
L	0.35	0.40	0.45
h	0.30	0.35	0.40



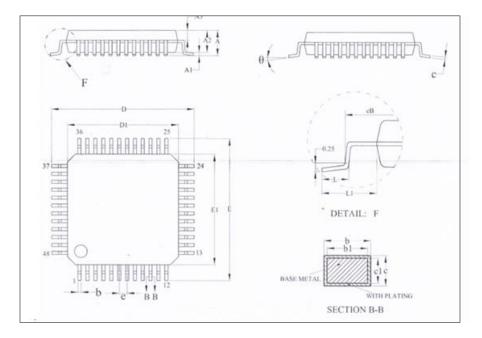
7.7 QFN40 (5x5mm,0.4mm spacing)



Symbol —	Millimeter			
	Min	Nom	Max	
A	0.70	0.75	0.80	
A1	-	0.02	0.05	
b	0.15	0.20	0.25	
С	0.18	0.20	0.25	
D	4.90	5.00	5.10	
D2	3.30	3.40	3.50	
е	0.40BSC			
Nd	3.60BSC			
E	4.90	5.00	5.10	
E2	3.30	3.40	3.50	
Ne	3.60BSC			
L	0.35	0.40	0.45	
К	0.20	-	-	
h	0.30	0.35	0.40	



7.8 LQFP48 (7x7mm,0.5mm spacing)



Symbol —	Millimeter			
	Min	Nom	Max	
A	-	-	1.60	
A1	0.05	-	0.15	
A2	1.35	1.40	1.45	
A3	0.59	0.64	0.69	
b	0.18	-	0.26	
b1	0.17	0.20	0.23	
С	0.13	-	0.17	
c1	0.12	0.13	0.14	
D	8.80	9.00	9.20	
D1	6.90	7.00	7.10	
E	8.80	9.00	9.20	
E1	6.90	7.00	7.10	
eB	8.10	-	8.25	
е	0.50BSC			
L	0.45	-	0.75	
L1	1.00REF			
θ	0	-	7°	



8 Revision History

Revision	Date	Modify content	
V1.00	May 2021	Original Issue	
V1.10	Aug 2021	6.5.2: misrepresentation	
V1.20	Sep 2021	1.3, 7.1, 7.2, 7.3: add package types	
V1.30	Oct 2021	1.3, 7.1, 7.2, 7.3: add package types	
V1.40	Nov 2021	1.3, 7.1, 7.2, 7.3: add package types	
V1.50	Dec 2021	6.5.2: modify power current	
V1.60	Mar 2022	1.3.2, 7.2: add package type	
V1.70	Jun 2022	4.1, 4.3: add port function and type5.7, 5.8:add Note for Low power consumption mode	
V1.80	Aug 2022	1.3, 7: adjust pin diagram format	
V1.90	Oct 2022	All chapter: niform format Change 6.3 Absolute maximum current rating and 6.4.2 Internal oscillator characteristics and standardize the format of electrical parameters	
V1.9.1	Dec 2022	In 6.5.2, modify the maximum value of clock running current of the subsystem; Modify partial power-off deep sleep mode current Corrected pin connection figure 1.3.4 In 6.10.1, add ESD electrical characteristics description In 6.4.2, Modify the temperature characteristics of the internal oscillator	
V1.9.2	Mar 2023	In 6.6, Correct parameters Table 4.1.3: Corrections	
V1.9.3	Apr 2023	Correct the encapsulation information in 7.3	
V1.9.4	Jun 2023	Delete the content and instructions related to the "deep sleep mode with partial power down".	